

TPA711

700-mW MONO LOW-VOLTAGE AUDIO POWER AMPLIFIER

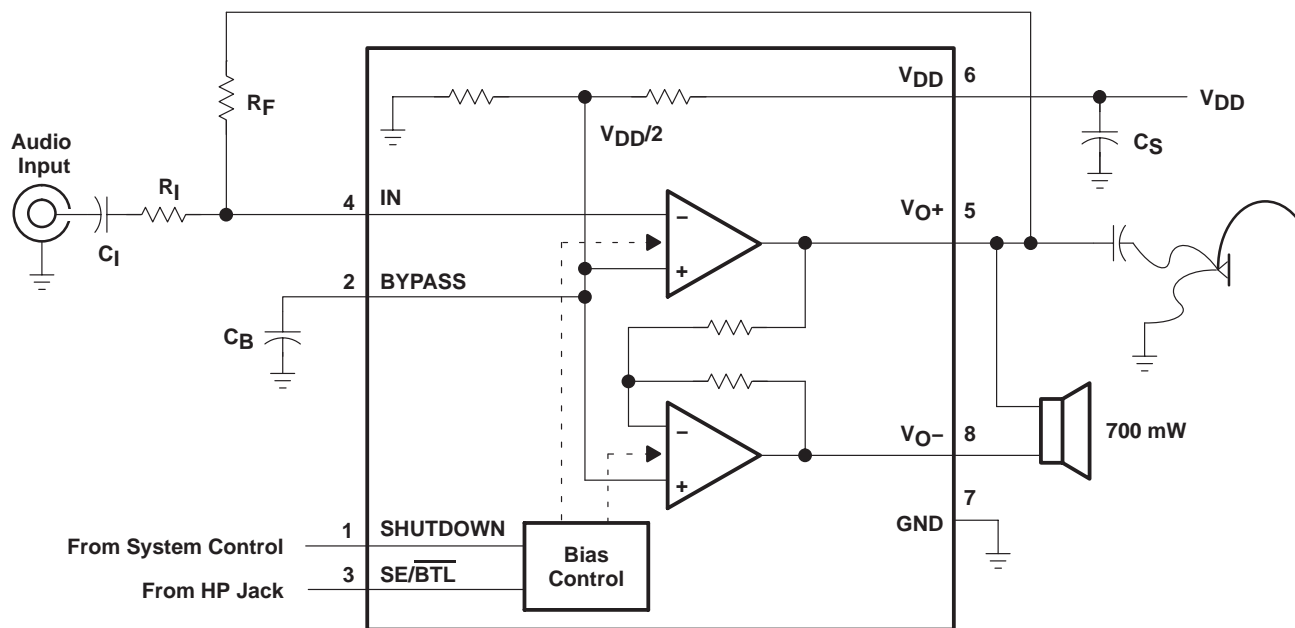
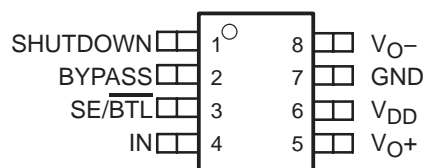
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- Fully Specified for 3.3-V and 5-V Operation
- Wide Power Supply Compatibility
2.5 V – 5.5 V
- Output Power
 - 700 mW at $V_{DD} = 5\text{ V}$, BTL, $R_L = 8\ \Omega$
 - 85 mW at $V_{DD} = 5\text{ V}$, SE, $R_L = 32\ \Omega$
 - 250 mW at $V_{DD} = 3.3\text{ V}$, BTL, $R_L = 8\ \Omega$
 - 37 mW at $V_{DD} = 3.3\text{ V}$, SE, $R_L = 32\ \Omega$
- Shutdown Control
 - $I_{DD} = 7\ \mu\text{A}$ at 3.3 V
 - $I_{DD} = 50\ \mu\text{A}$ at 5 V
- BTL to SE Mode Control
- Integrated Depop Circuitry
- Thermal and Short-Circuit Protection
- Surface-Mount Packaging
 - SOIC
 - PowerPAD™ MSOP

description

The TPA711 is a bridge-tied load (BTL) or single-ended (SE) audio power amplifier developed especially for low-voltage applications where internal speakers and external earphone operation are required. Operating with a 3.3-V supply, the TPA711 can deliver 250-mW of continuous power into a BTL 8- Ω load at less than 0.6% THD+N throughout voice band frequencies. Although this device is characterized out to 20 kHz, its operation is optimized for narrower band applications such as wireless communications. The BTL configuration eliminates the need for external coupling capacitors on the output in most applications, which is particularly important for small battery-powered equipment. A unique feature of the TPA711 is that it allows the amplifier to switch from BTL to SE *on the fly* when an earphone drive is required. This eliminates complicated mechanical switching or auxiliary devices just to drive the external load. This device features a shutdown mode for power-sensitive applications with special depop circuitry to eliminate speaker noise when exiting shutdown mode. The TPA711 is available in an 8-pin SOIC and the surface-mount PowerPAD MSOP package, which reduces board space by 50% and height by 40%.

D OR DGN PACKAGE
(TOP VIEW)



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PowerPAD is a trademark of Texas Instruments.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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AVAILABLE OPTIONS

T _A	PACKAGED DEVICES		MSOP SYMBOLIZATION
	SMALL OUTLINE† (D)	MSOP‡ (DGN)	
-40°C to 85°C	TPA711D	TPA711DGN	ABB

† In the SOIC package, the maximum RMS output power is thermally limited to 350 mW; 700 mW peaks can be driven, as long as the RMS value is less than 350 mW.

‡ The D and DGN packages are available taped and reeled. To order a taped and reeled part, add the suffix R to the part number (e.g., TPA311DR).

Terminal Functions

TERMINAL NAME	NO.	I/O	DESCRIPTION
BYPASS	2	I	BYPASS is the tap to the voltage divider for internal mid-supply bias. This terminal should be connected to a 0.1-μF to 2.2-μF capacitor when used as an audio amplifier.
GND	7		GND is the ground connection.
IN	4	I	IN is the audio input terminal.
SE/BTL	3	I	When SE/BTL is held low, the TPA711 is in BTL mode. When SE/BTL is held high, the TPA711 is in SE mode.
SHUTDOWN	1	I	SHUTDOWN places the entire device in shutdown mode when held high (I _{DD} = 7 μA).
V _{DD}	6		V _{DD} is the supply voltage terminal.
V _{O+}	5	O	V _{O+} is the positive output for BTL and SE modes.
V _{O-}	8	O	V _{O-} is the negative output in BTL mode and a high-impedance output in SE mode.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)§

Supply voltage, V _{DD}	6 V
Input voltage, V _I	-0.3 V to V _{DD} + 0.3 V
Continuous total power dissipation	Internally limited (see Dissipation Rating Table)
Operating free-air temperature range, T _A (see Table 3)	-40°C to 85°C
Operating junction temperature range, T _J	-40°C to 150°C
Storage temperature range, T _{stg}	-65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

§ Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C	DERATING FACTOR	T _A = 70°C	T _A = 85°C
D	725 mW	5.8 mW/°C	464 mW	377 mW
DGN	2.14 W [¶]	17.1 mW/°C	1.37 W	1.11 W

¶ Please see the Texas Instruments document, *PowerPAD Thermally Enhanced Package Application Report* (SLMA002), for more information on the PowerPAD package. The thermal data was measured on a PCB layout based on the information in the section entitled *Texas Instruments Recommended Board for PowerPAD* on page 33 of that document.



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recommended operating conditions

		MIN	MAX	UNIT
Supply voltage, V_{DD}		2.5	5.5	V
High-level voltage, V_{IH}	SHUTDOWN	$0.9V_{DD}$		V
	SE/BTL	$0.9V_{DD}$		
Low-level voltage, V_{IL}	SHUTDOWN	$0.1V_{DD}$		V
	SE/BTL	$0.1V_{DD}$		
Operating free-air temperature, T_A (see Table 3)		-40	85	°C

electrical characteristics at specified free-air temperature, $V_{DD} = 3.3$ V, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{OO} Output offset voltage (measured differentially)	SHUTDOWN = 0 V, SE/BTL = 0 V, $R_L = 8 \Omega$, $R_F = 10 \text{ k}\Omega$			20	mV
PSRR Power supply rejection ratio	$V_{DD} = 3.2$ V to 3.4 V	BTL mode	85		dB
		SE mode	83		
I_{DD} Supply current (see Figure 6)	BTL mode, SHUTDOWN = 0 V, SE/BTL = 0.33 V, $R_F = 10 \text{ k}\Omega$		1.25	2.5	mA
	SE mode, SHUTDOWN = 0 V, SE/BTL = 2.97 V, $R_F = 10 \text{ k}\Omega$		0.65	1.25	
$I_{DD(SD)}$ Supply current, shutdown mode (see Figure 7)	SE/BTL = 2.97 V, SHUTDOWN = V_{DD} , $R_F = 10 \text{ k}\Omega$		7	50	μA
$ I_{IH} $	SHUTDOWN, $V_{DD} = 3.3$ V, $V_I = V_{DD}$			1	μA
	SE/BTL, $V_{DD} = 3.3$ V, $V_I = V_{DD}$			1	
$ I_{IL} $	SHUTDOWN, $V_{DD} = 3.3$ V, $V_I = 0$ V			1	μA
	SE/BTL, $V_{DD} = 3.3$ V, $V_I = 0$ V			1	

operating characteristics, $V_{DD} = 3.3$ V, $T_A = 25^\circ\text{C}$, $R_L = 8 \Omega$

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
P_O Output power, see Note 1	THD = 0.2%, BTL mode, See Figure 14		250		mW
	THD = 0.1%, SE mode, $R_L = 32 \Omega$, See Figure 22		37		
THD + N Total harmonic distortion plus noise	$P_O = 250$ mW, $f = 200$ Hz to 4 kHz, See Figure 12		0.55%		
B_{OM} Maximum output power bandwidth	Gain = 2, THD = 2%, See Figure 12		20		kHz
B_1 Unity-gain bandwidth	Open Loop, See Figure 36		1.4		MHz
Supply ripple rejection ratio	$f = 1$ kHz, $C_B = 1 \mu\text{F}$, BTL mode, See Figure 5		79		dB
	$f = 1$ kHz, $C_B = 1 \mu\text{F}$, SE mode, See Figure 3		70		
V_n Noise output voltage	Gain = 1, $C_B = 0.1 \mu\text{F}$, See Figure 42		17		$\mu\text{V(rms)}$

NOTE 1: Output power is measured at the output terminals of the device at $f = 1$ kHz.



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electrical characteristics at specified free-air temperature, $V_{DD} = 5\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_{OO}	Output offset voltage (measured differentially)	SHUTDOWN = 0 V, SE/BTL = 0 V, $R_L = 8\ \Omega$, $R_F = 10\ \text{k}\Omega$				20	mV
PSRR	Power supply rejection ratio	$V_{DD} = 4.9\text{ V to } 5.1\text{ V}$	BTL mode		78		dB
			SE mode		76		
I_{DD}	Supply current (see Figure 6)	BTL mode, SHUTDOWN = 0 V, SE/BTL = 0.5 V, $R_F = 10\ \text{k}\Omega$			1.25	2.5	mA
		SE mode, SHUTDOWN = 0 V, SE/BTL = 4.5 V, $R_F = 10\ \text{k}\Omega$			0.65	1.25	
$I_{DD(SD)}$	Supply current, shutdown mode (see Figure 7)	SE/BTL = 0 V, SHUTDOWN = V_{DD} , $R_F = 10\ \text{k}\Omega$			50	100	μA
$ I_{IH} $		SHUTDOWN, $V_{DD} = 5.5\text{ V}$, $V_I = V_{DD}$				1	μA
		SE/BTL, $V_{DD} = 5.5\text{ V}$, $V_I = V_{DD}$				1	
$ I_{IL} $		SHUTDOWN, $V_{DD} = 5.5\text{ V}$, $V_I = 0\text{ V}$				1	μA
		SE/BTL, $V_{DD} = 5.5\text{ V}$, $V_I = 0\text{ V}$				1	

operating characteristics, $V_{DD} = 5\text{ V}$, $T_A = 25^\circ\text{C}$, $R_L = 8\ \Omega$

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
P_O	Output power, see Note 1	THD = 0.3%,	BTL mode, See Figure 18		700 [†]		mW
		THD = 0.1%, See Figure 26	SE mode, $R_L = 32\ \Omega$,		85		
THD + N	Total harmonic distortion plus noise	$P_O = 700\text{ mW}$, $f = 200\text{ Hz to } 4\text{ kHz}$, See Figure 16			0.5%		
B_{OM}	Maximum output power bandwidth	Gain = 2,	THD = 2%, See Figure 16		20		kHz
B_1	Unity-gain bandwidth	Open Loop,	See Figure 37		1.4		MHz
	Supply ripple rejection ratio	$f = 1\text{ kHz}$, See Figure 5	$C_B = 1\ \mu\text{F}$, BTL mode,		80		dB
		$f = 1\text{ kHz}$, See Figure 4	$C_B = 1\ \mu\text{F}$, SE mode,		73		
V_n	Noise output voltage	Gain = 1,	$C_B = 0.1\ \mu\text{F}$, See Figure 43		17		$\mu\text{V(rms)}$

[†] The DGN package, properly mounted, can conduct 700 mW RMS power continuously. The D package, can only conduct 350 mW RMS power continuously, with peaks to 700 mW.

NOTE 1: Output power is measured at the output terminals of the device at $f = 1\text{ kHz}$.



PARAMETER MEASUREMENT INFORMATION

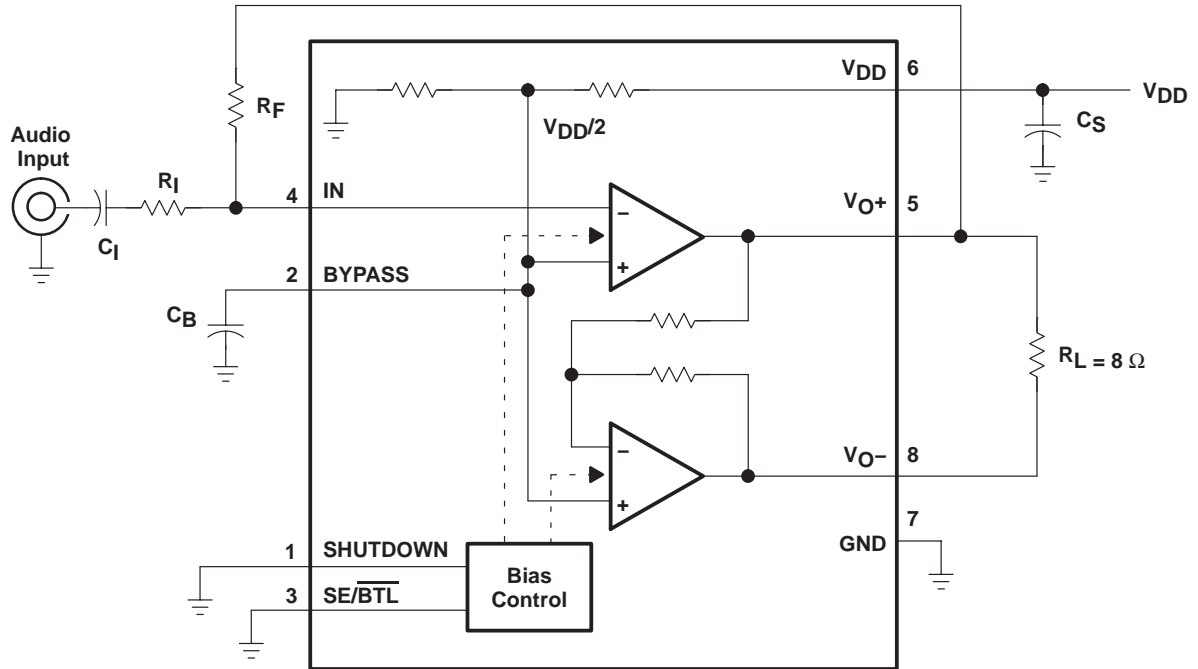


Figure 1. BTL Mode Test Circuit

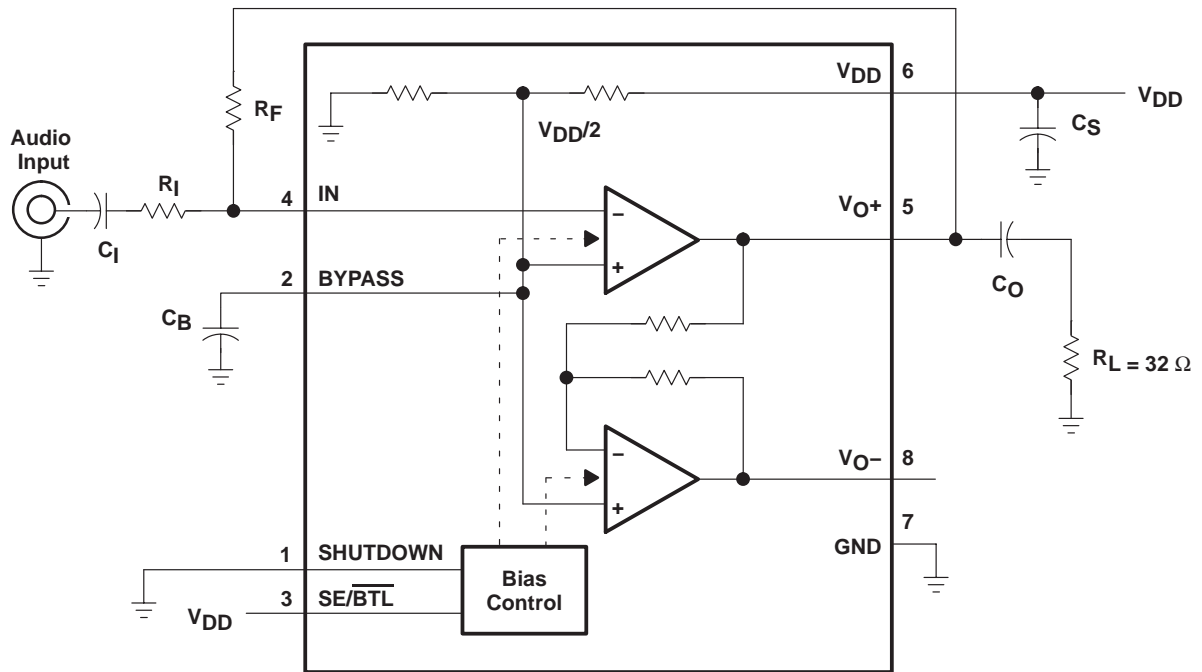


Figure 2. SE Mode Test Circuit

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TYPICAL CHARACTERISTICS

Table of Graphs

		FIGURE	
	Supply ripple rejection ratio	vs Frequency	3, 4, 5
I_{DD}	Supply current	vs Supply voltage	6, 7
P_O	Output power	vs Supply voltage	8, 9
		vs Load resistance	10, 11
THD+N	Total harmonic distortion plus noise	vs Frequency	12, 13, 16, 17, 20, 21, 24, 25, 28, 29, 32, 33
		vs Output power	14, 15, 18, 19, 22, 23, 26, 27, 30, 31, 34, 35
	Open loop gain and phase	vs Frequency	36, 37
	Closed loop gain and phase	vs Frequency	38, 39, 40, 41
V_n	Output noise voltage	vs Frequency	42, 43
P_D	Power dissipation	vs Output power	44, 45, 46, 47

SUPPLY RIPPLE REJECTION RATIO
vs
FREQUENCY

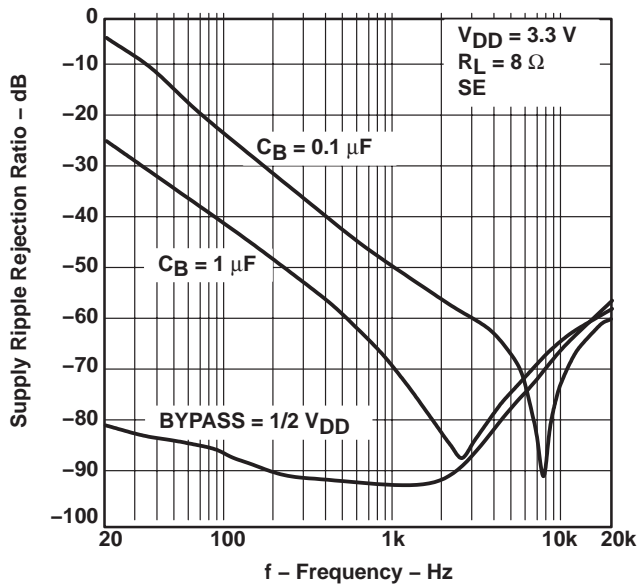


Figure 3

SUPPLY RIPPLE REJECTION RATIO
vs
FREQUENCY

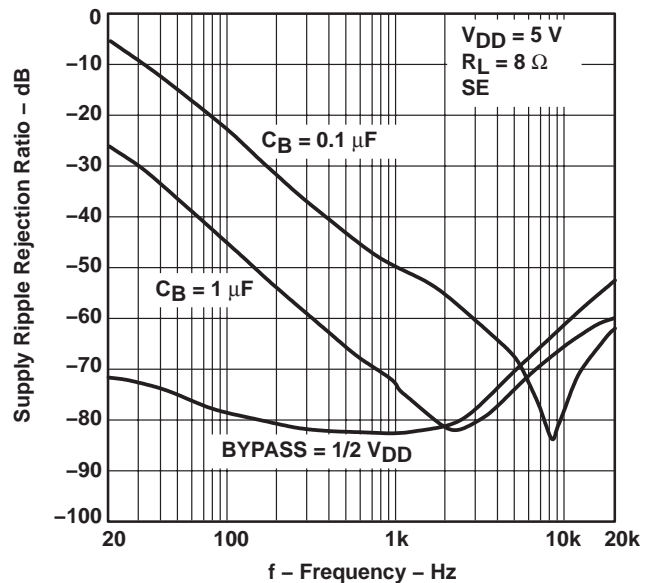


Figure 4

TYPICAL CHARACTERISTICS

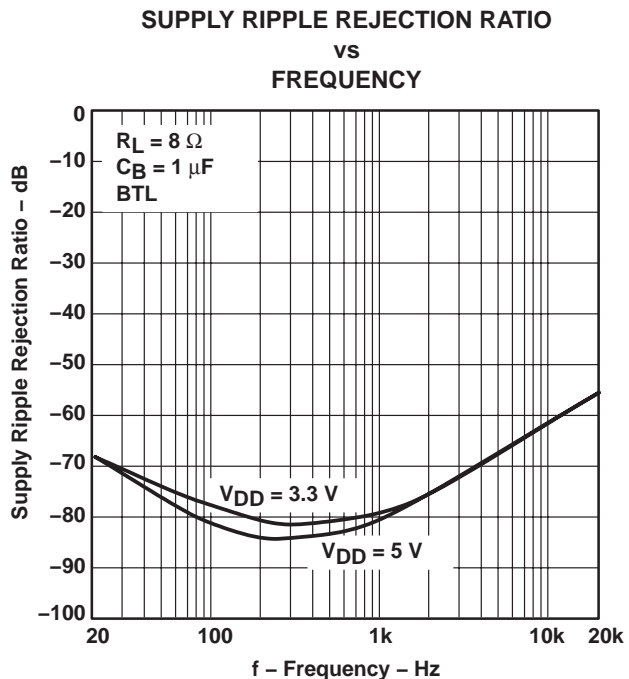


Figure 5

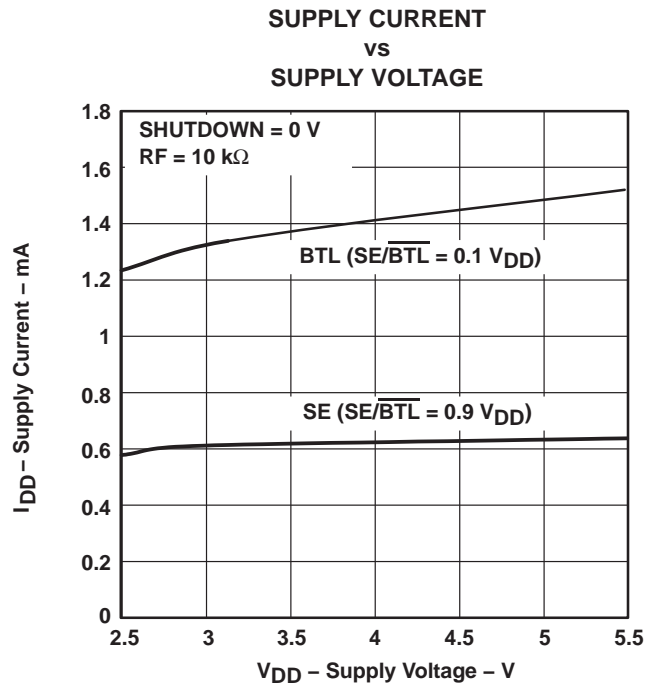


Figure 6

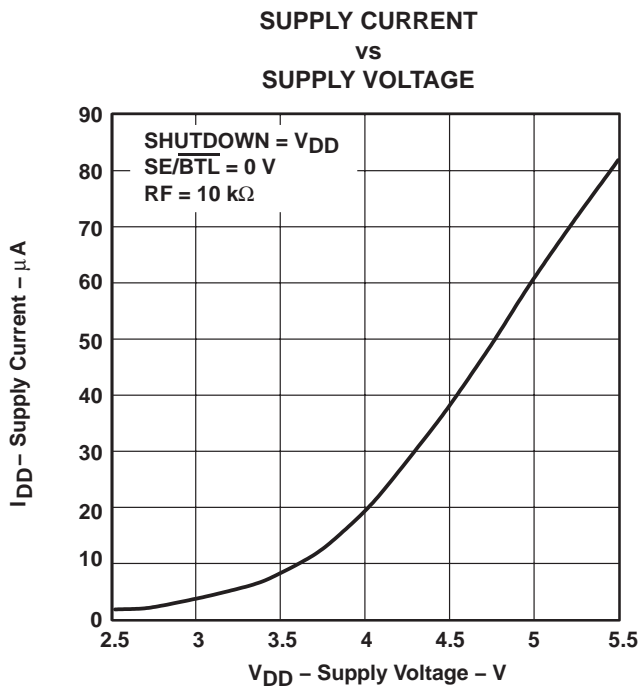


Figure 7

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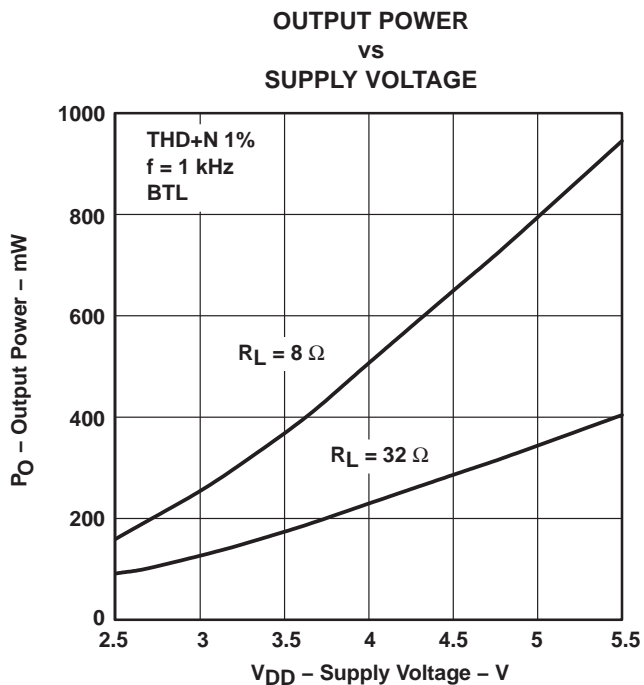


Figure 8

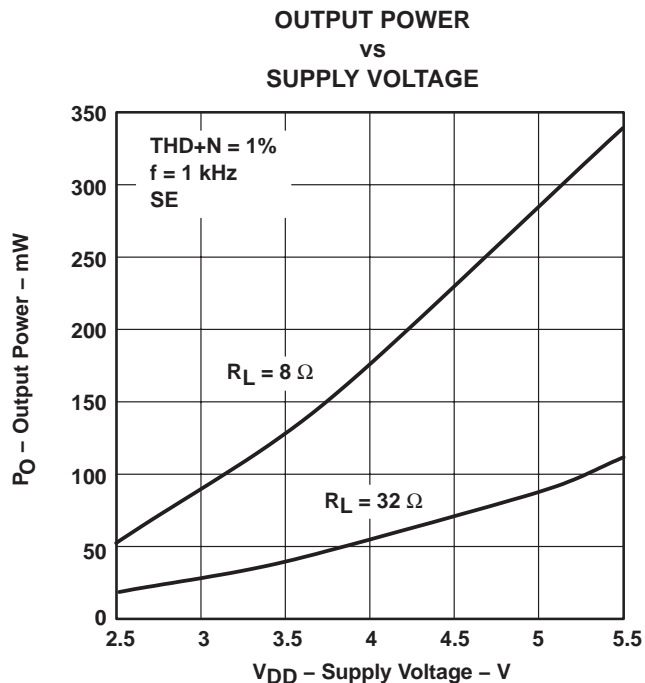


Figure 9

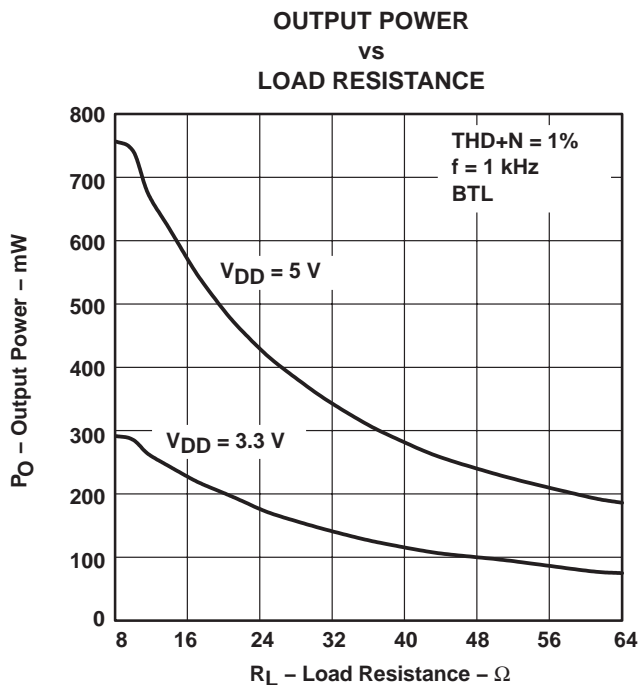


Figure 10

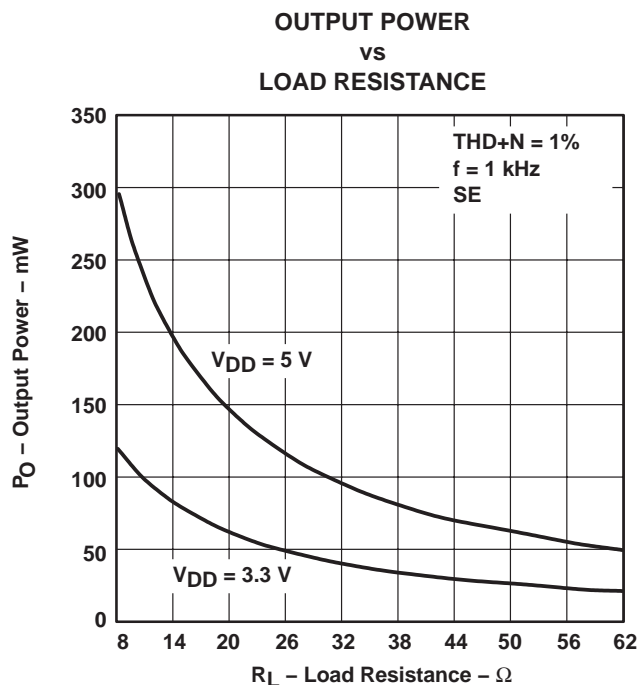


Figure 11

TYPICAL CHARACTERISTICS

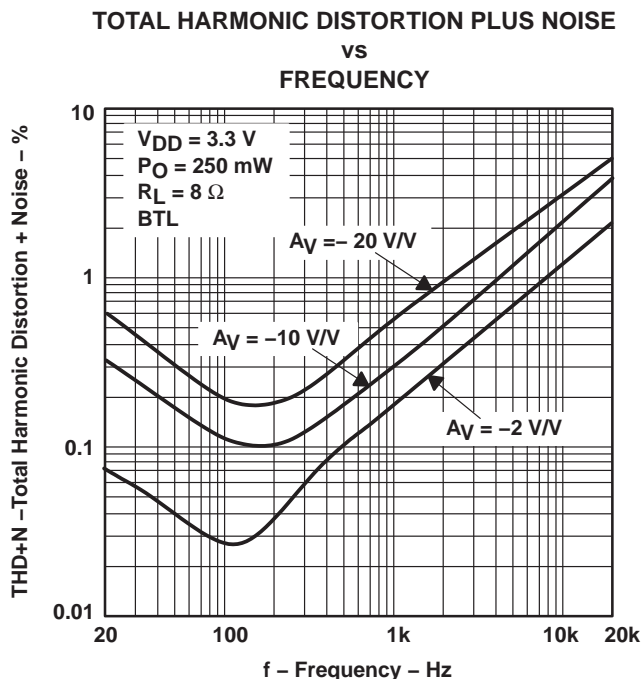


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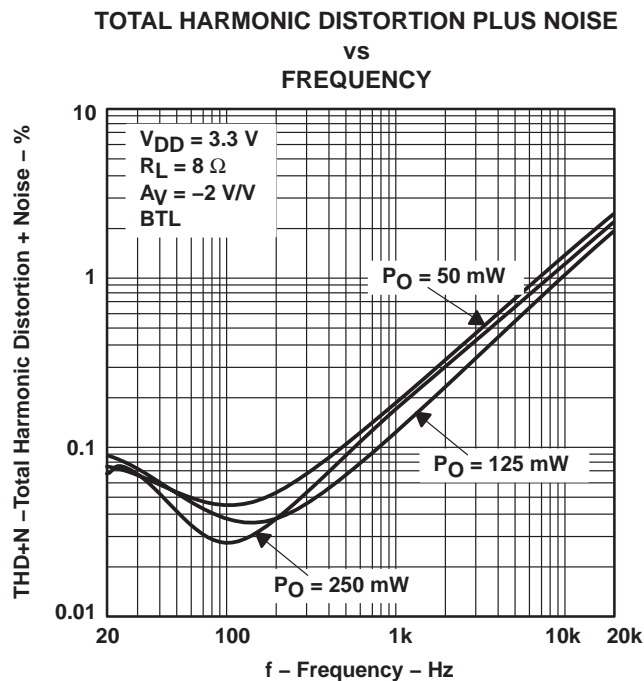


Figure 13

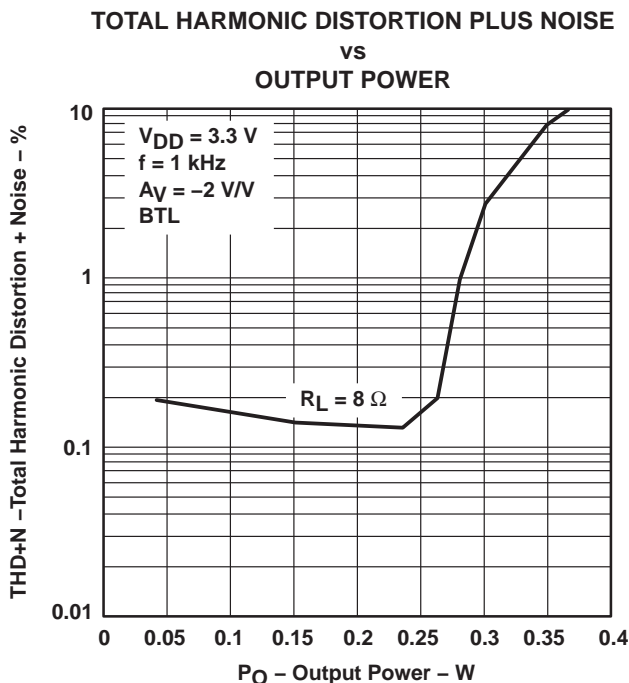


Figure 14

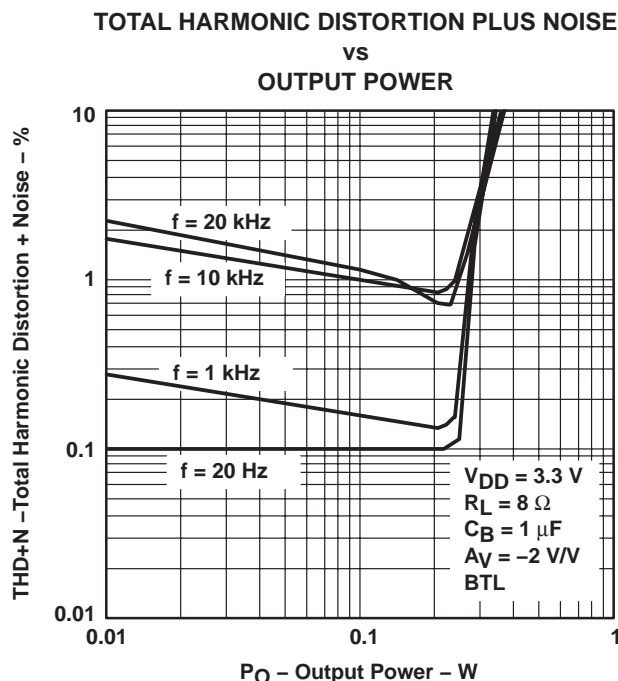


Figure 15

TPA711 700-mW MONO LOW-VOLTAGE AUDIO POWER AMPLIFIER

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TYPICAL CHARACTERISTICS

TOTAL HARMONIC DISTORTION PLUS NOISE
vs
FREQUENCY

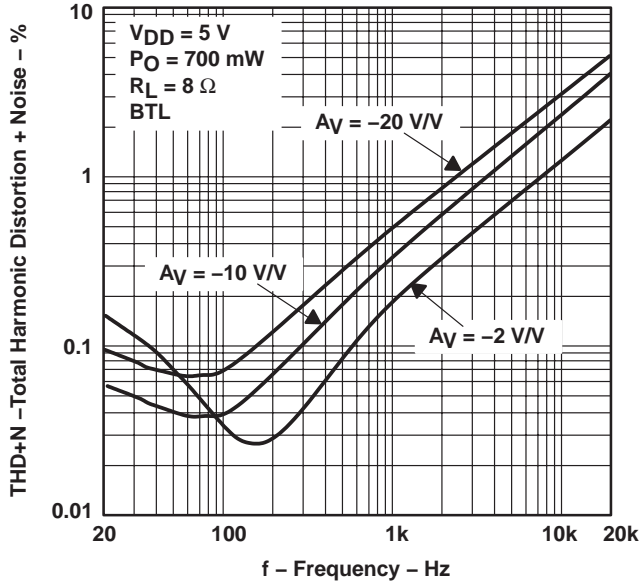


Figure 16

TOTAL HARMONIC DISTORTION PLUS NOISE
vs
FREQUENCY

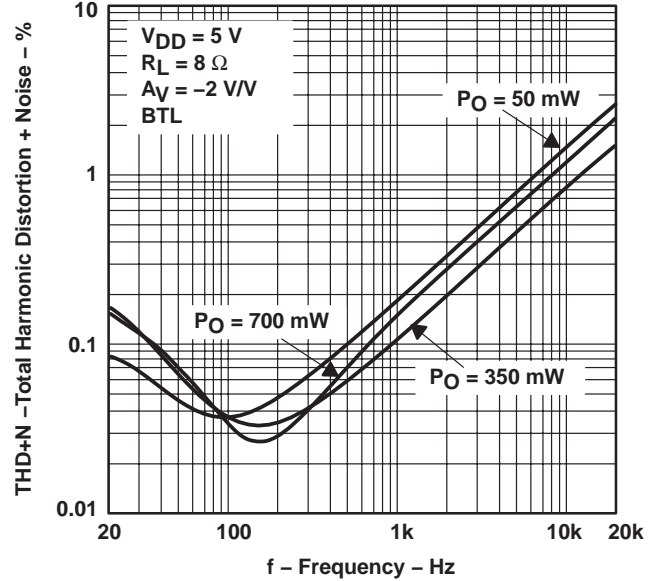


Figure 17

TOTAL HARMONIC DISTORTION PLUS NOISE
vs
OUTPUT POWER

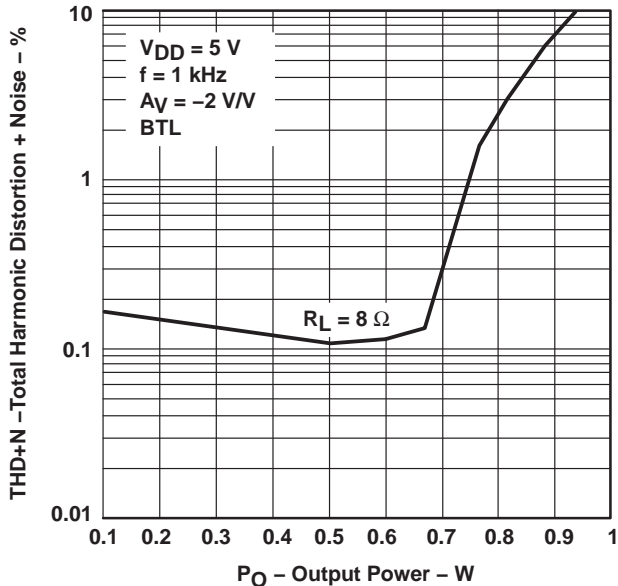


Figure 18

TOTAL HARMONIC DISTORTION PLUS NOISE
vs
OUTPUT POWER

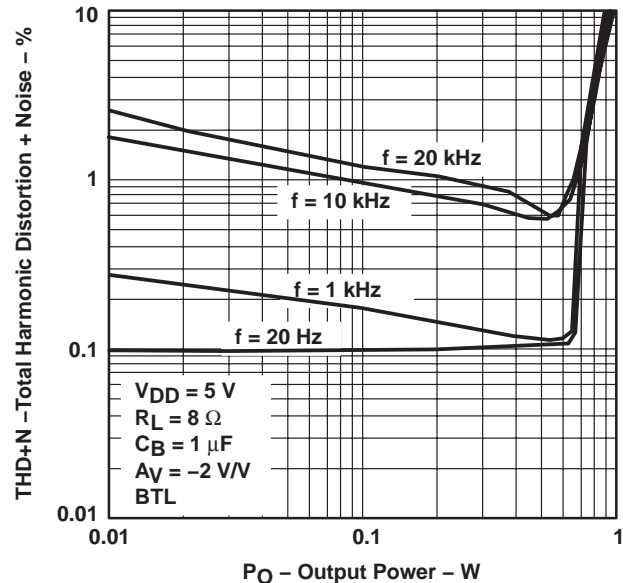


Figure 19

TYPICAL CHARACTERISTICS

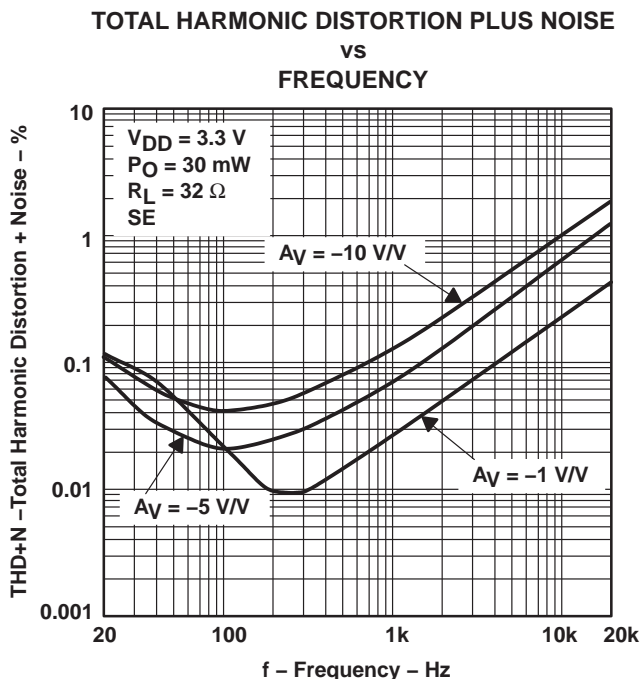


Figure 20

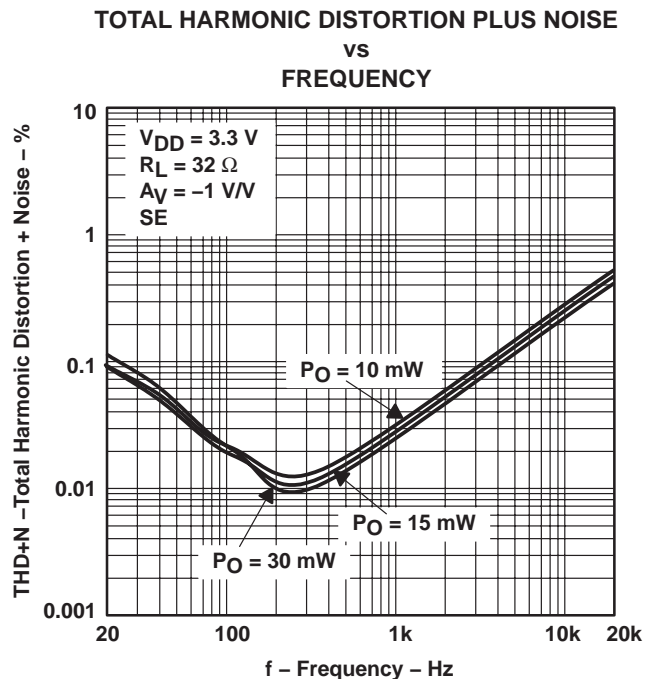


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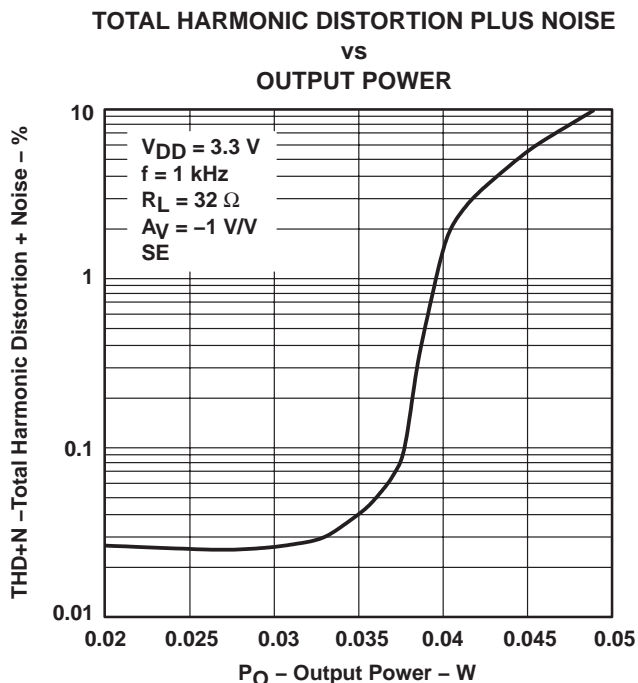


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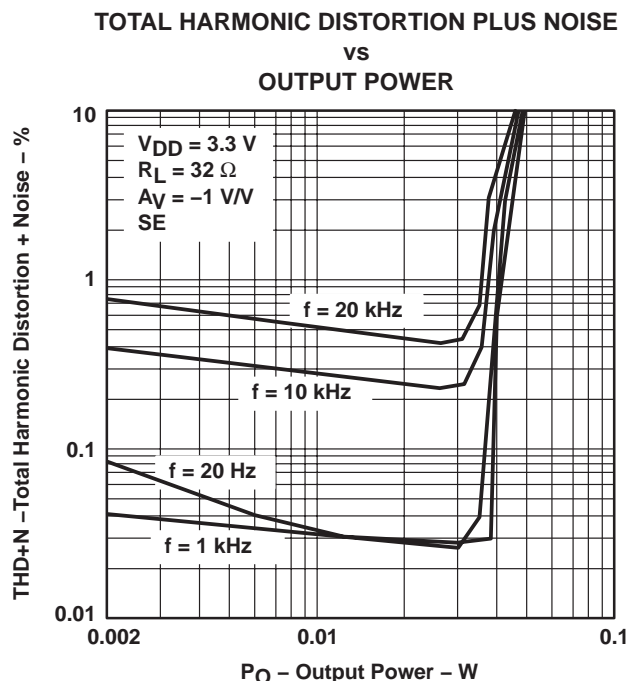


Figure 23

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TYPICAL CHARACTERISTICS

**TOTAL HARMONIC DISTORTION PLUS NOISE
vs
FREQUENCY**

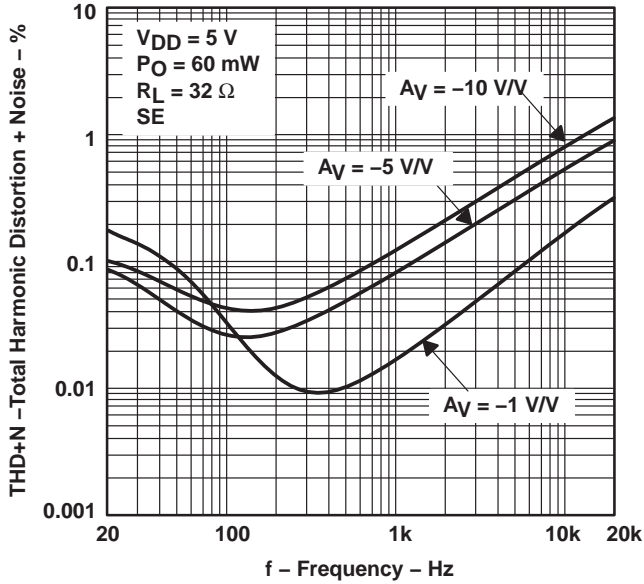


Figure 24

**TOTAL HARMONIC DISTORTION PLUS NOISE
vs
FREQUENCY**

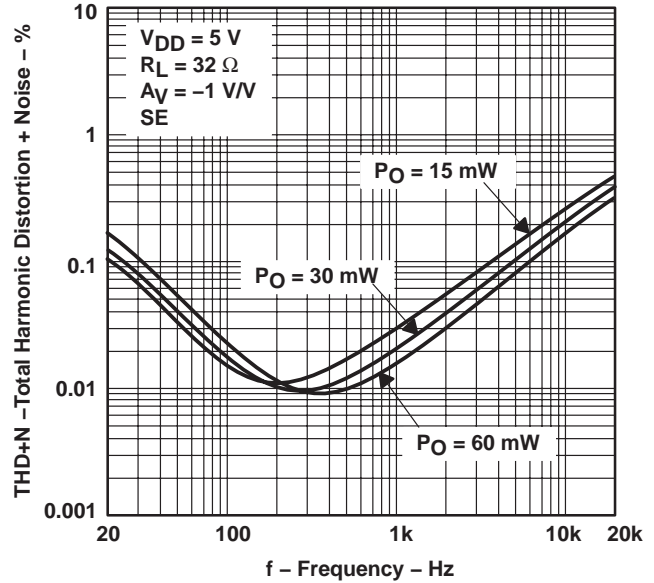


Figure 25

**TOTAL HARMONIC DISTORTION PLUS NOISE
vs
OUTPUT POWER**

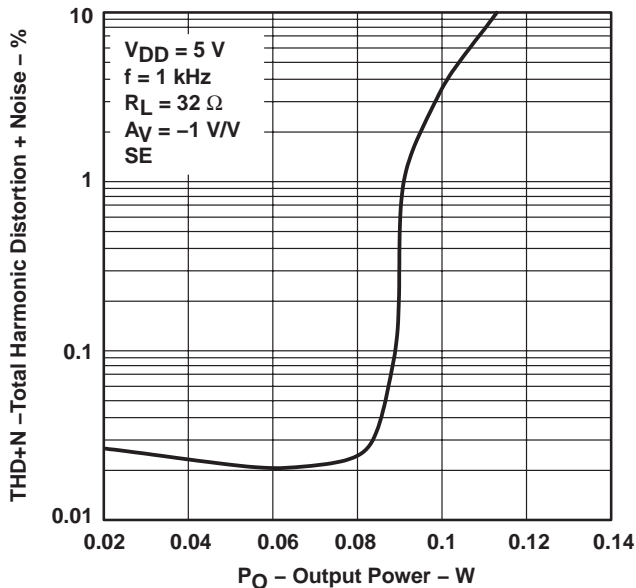


Figure 26

**TOTAL HARMONIC DISTORTION PLUS NOISE
vs
OUTPUT POWER**

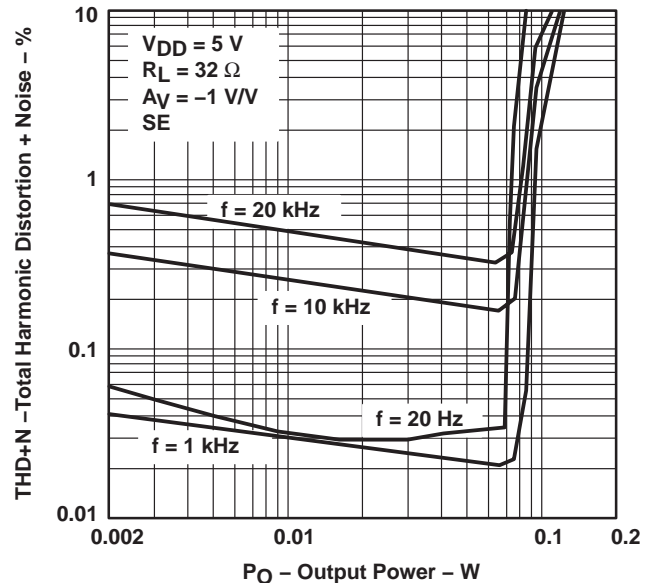


Figure 27



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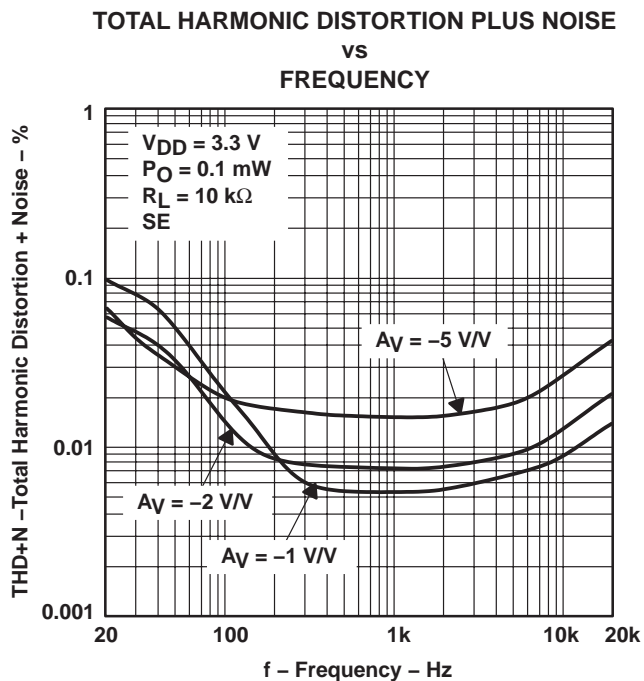


Figure 28

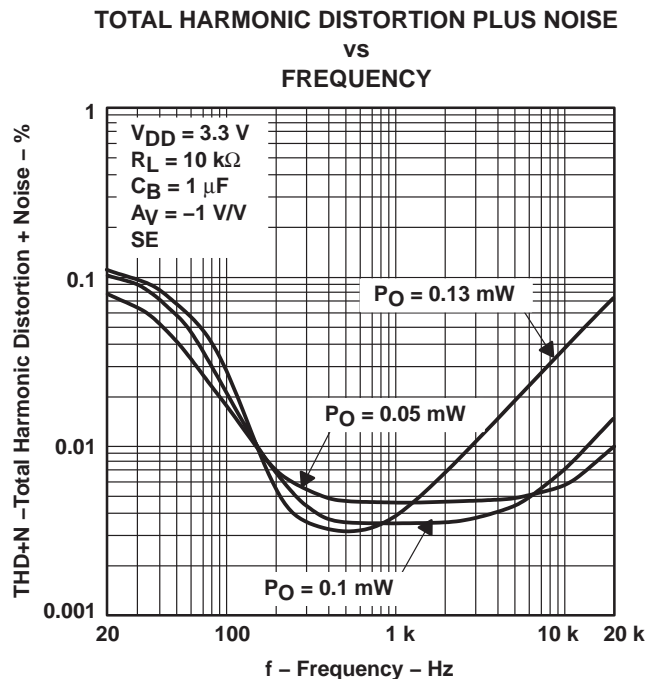


Figure 29

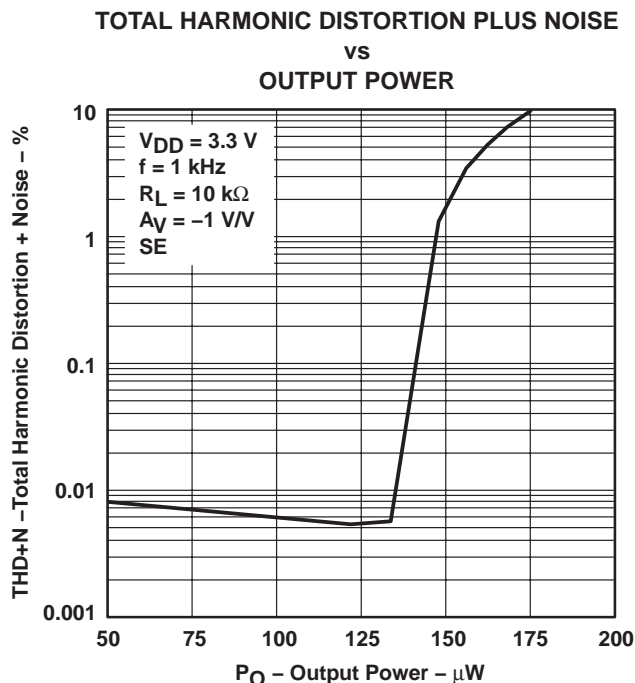


Figure 30

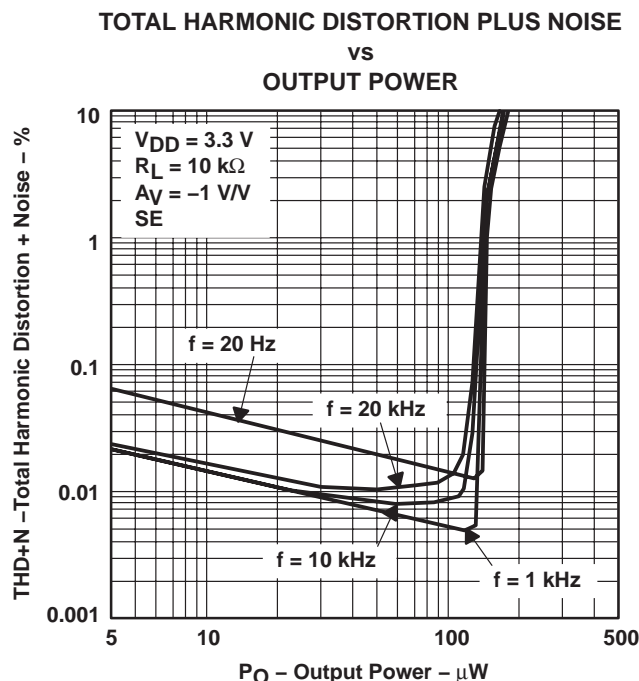


Figure 31

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TYPICAL CHARACTERISTICS

**TOTAL HARMONIC DISTORTION PLUS NOISE
vs
FREQUENCY**

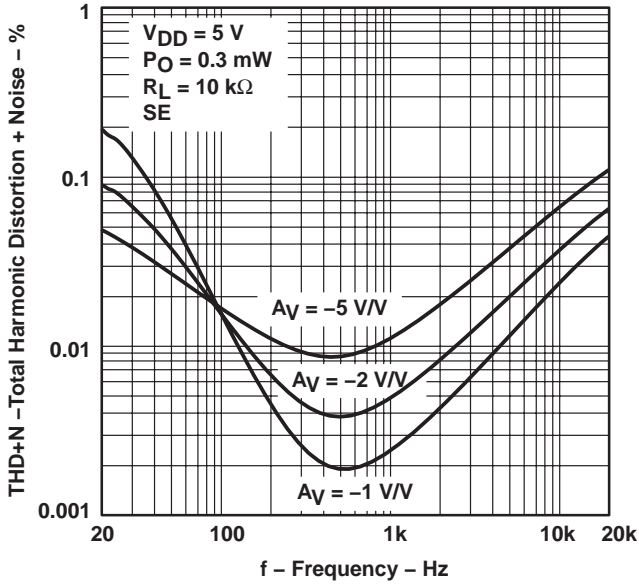


Figure 32

**TOTAL HARMONIC DISTORTION PLUS NOISE
vs
FREQUENCY**

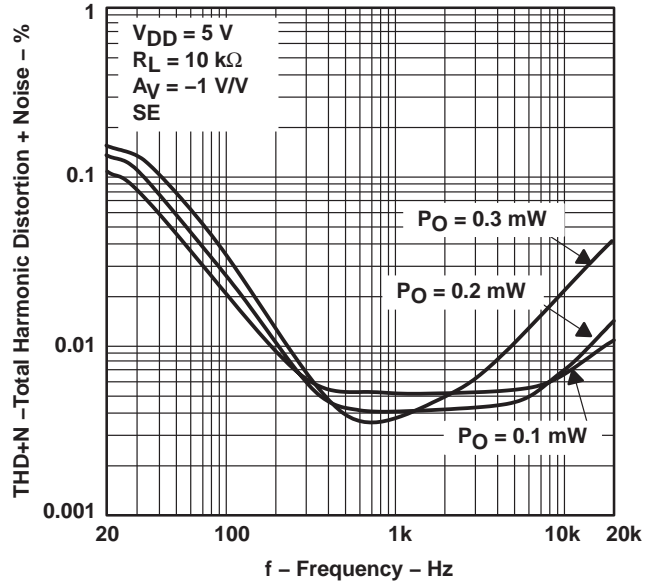


Figure 33

**TOTAL HARMONIC DISTORTION PLUS NOISE
vs
OUTPUT POWER**

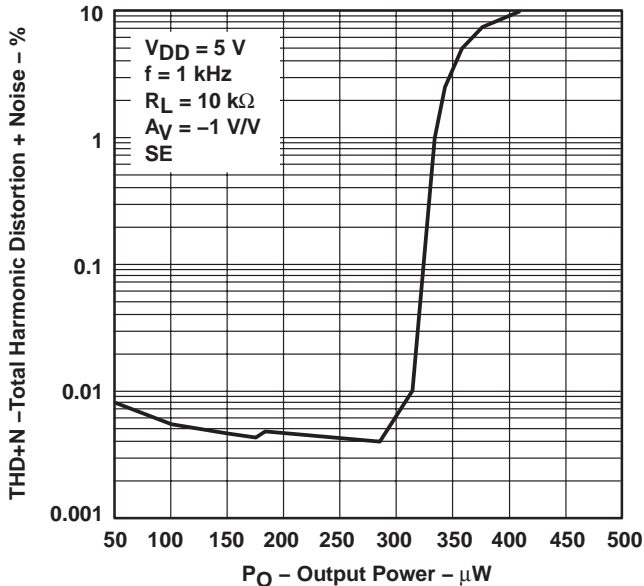


Figure 34

**TOTAL HARMONIC DISTORTION PLUS NOISE
vs
OUTPUT POWER**

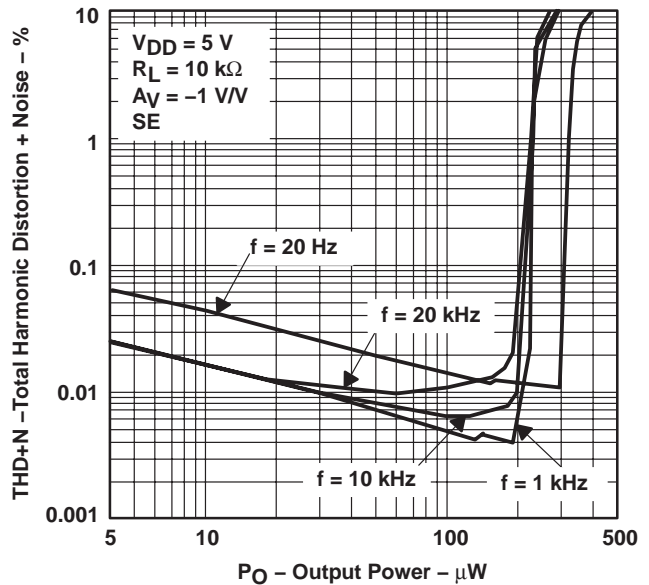


Figure 35

TYPICAL CHARACTERISTICS

**OPEN-LOOP GAIN AND PHASE
vs
FREQUENCY**

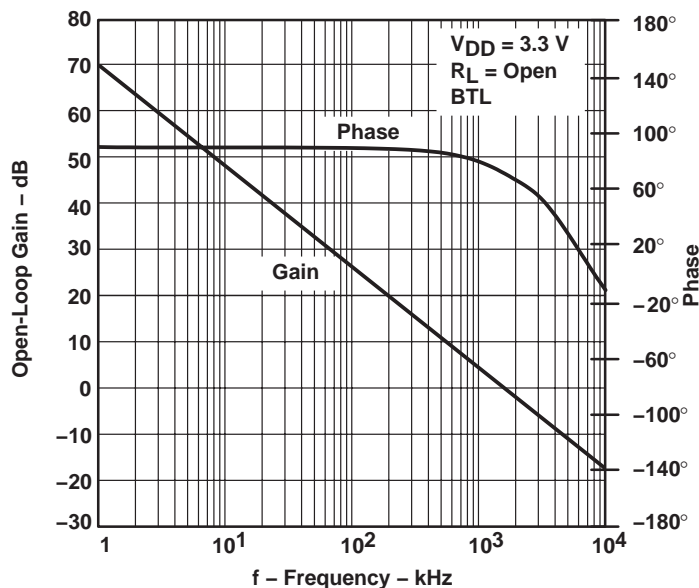


Figure 36

**OPEN-LOOP GAIN AND PHASE
vs
FREQUENCY**

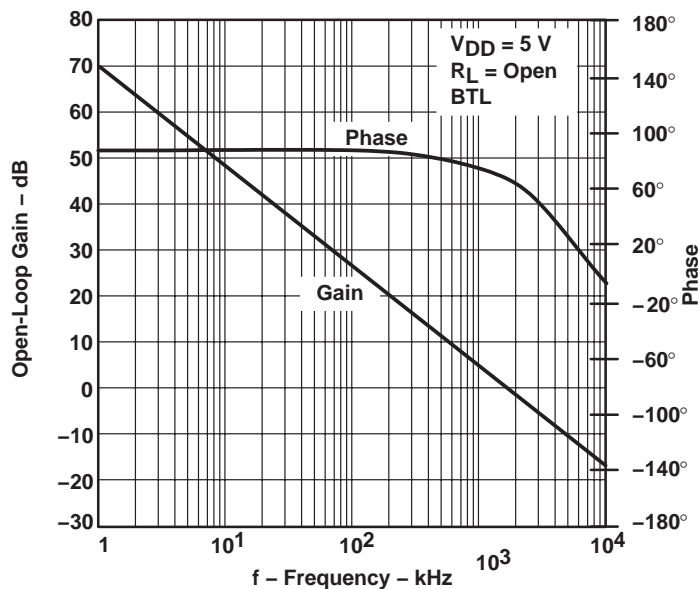


Figure 37

TPA711 700-mW MONO LOW-VOLTAGE AUDIO POWER AMPLIFIER

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TYPICAL CHARACTERISTICS

CLOSED-LOOP GAIN AND PHASE vs FREQUENCY

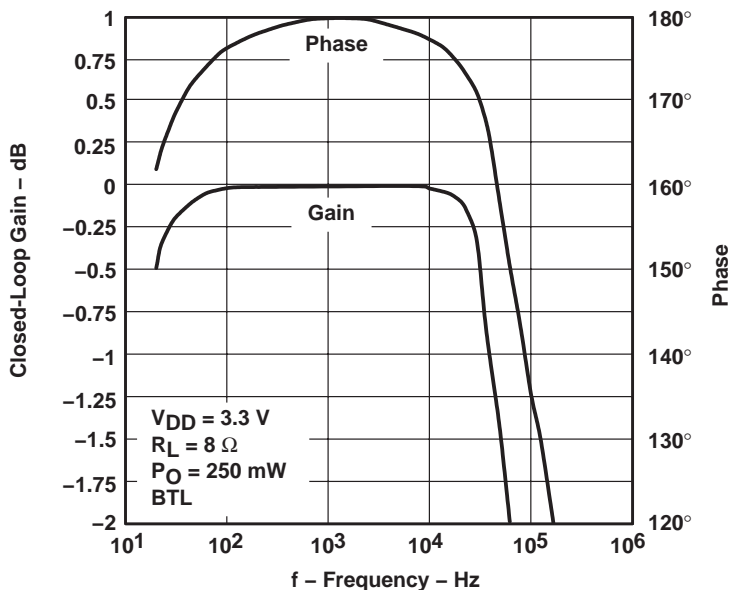


Figure 38

CLOSED-LOOP GAIN AND PHASE vs FREQUENCY

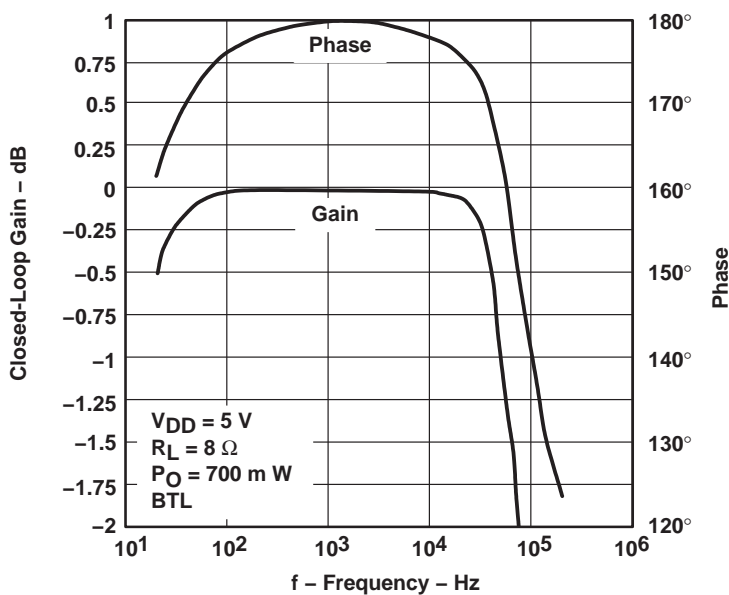


Figure 39



TYPICAL CHARACTERISTICS

**CLOSED-LOOP GAIN AND PHASE
vs
FREQUENCY**

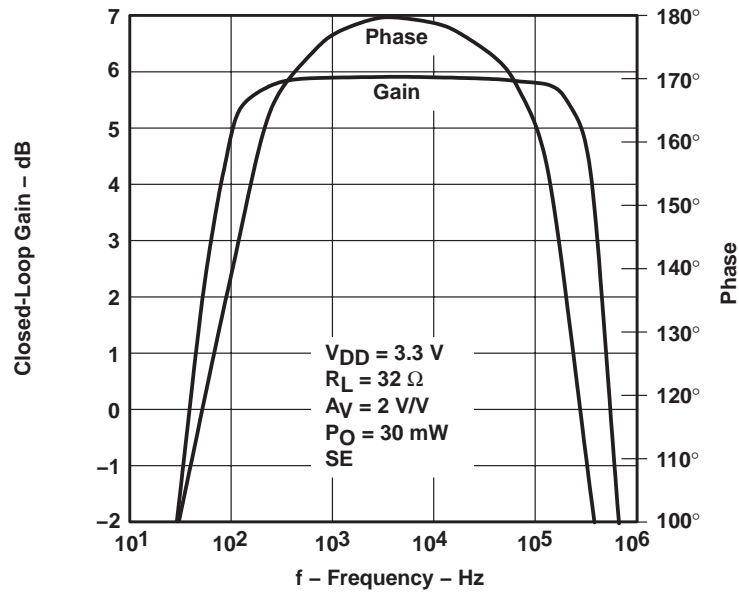


Figure 40

**CLOSED-LOOP GAIN AND PHASE
vs
FREQUENCY**

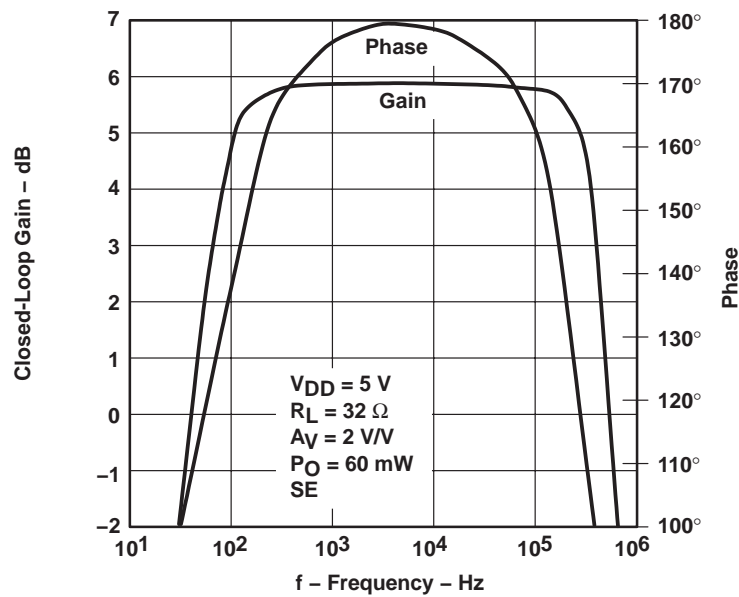


Figure 41

TPA711 700-mW MONO LOW-VOLTAGE AUDIO POWER AMPLIFIER

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TYPICAL CHARACTERISTICS

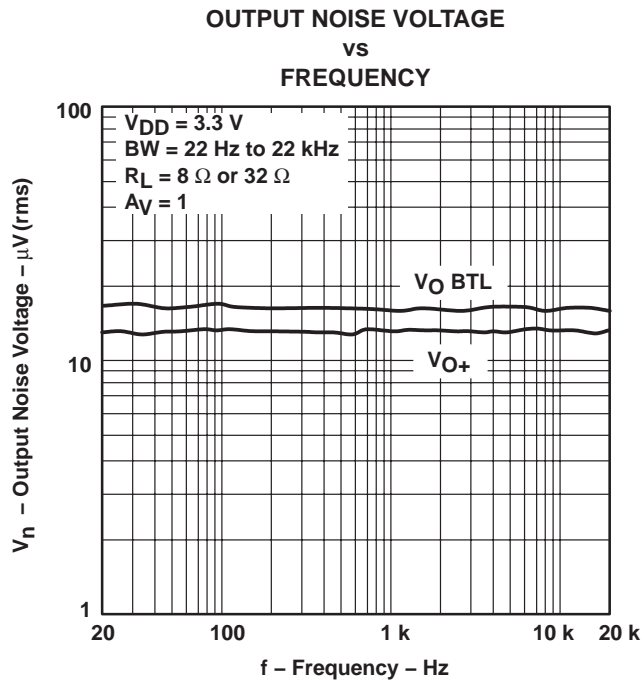


Figure 42

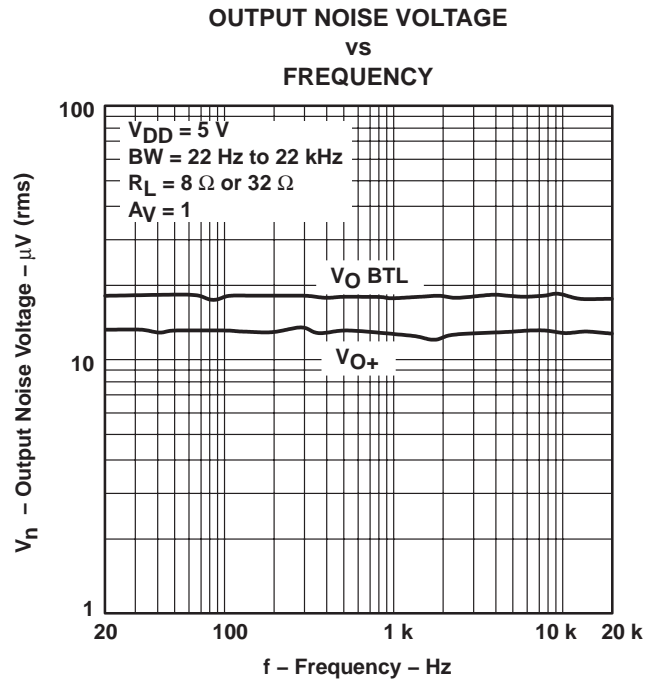


Figure 43

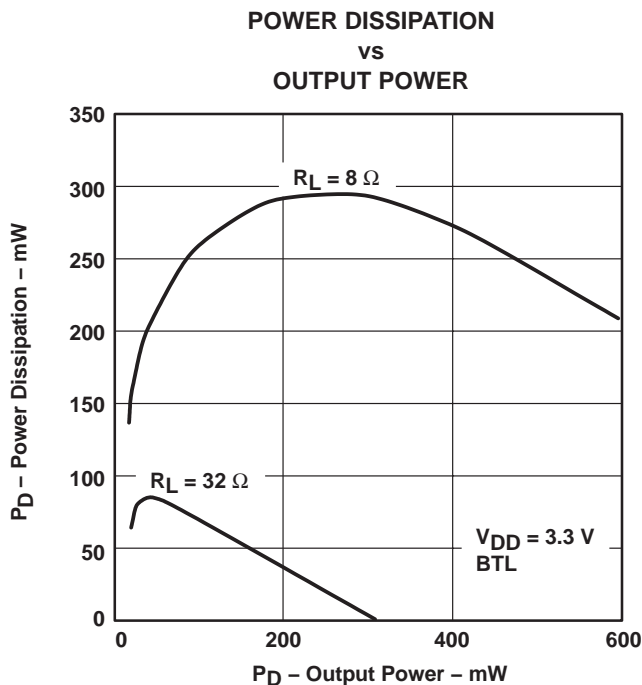


Figure 44

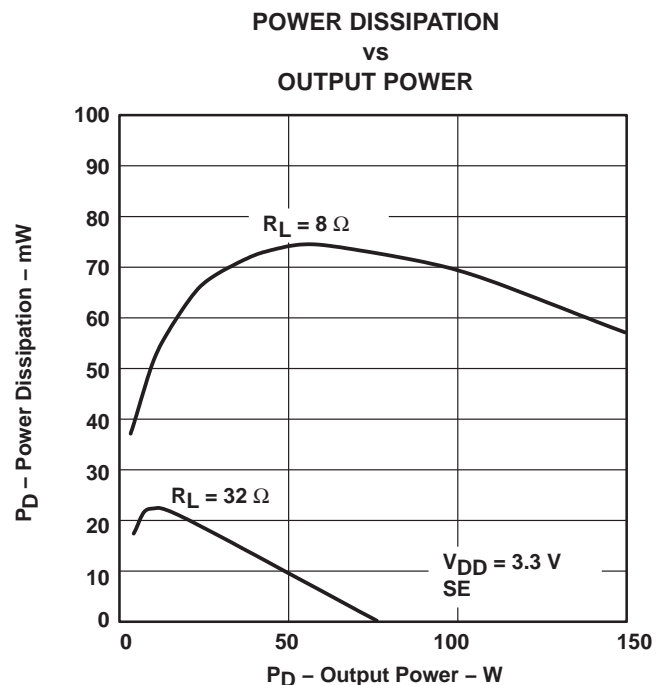


Figure 45

TYPICAL CHARACTERISTICS

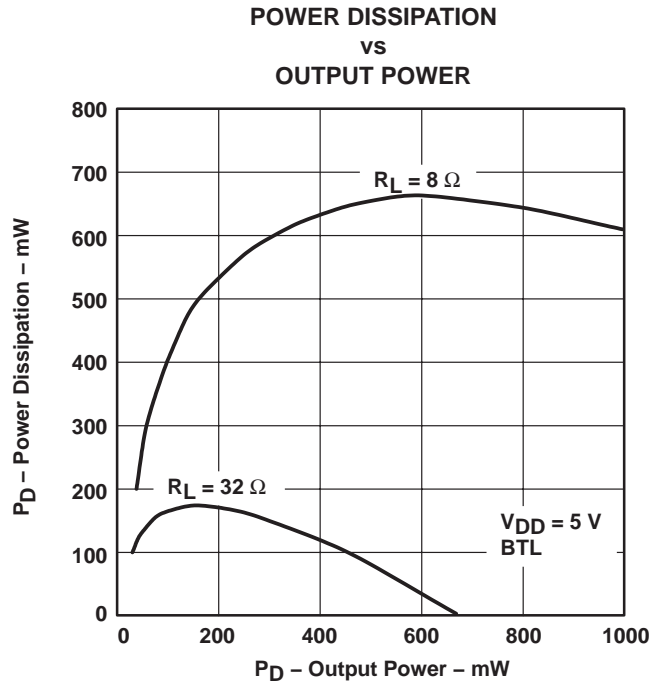


Figure 46

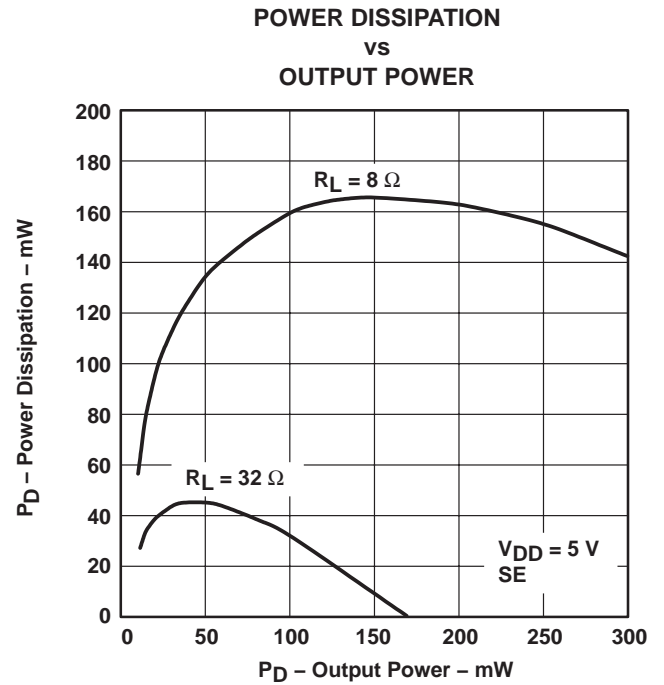


Figure 47

TPA711 700-mW MONO LOW-VOLTAGE AUDIO POWER AMPLIFIER

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APPLICATION INFORMATION

bridged-tied load versus single-ended mode

Figure 48 shows a linear audio power amplifier (APA) in a BTL configuration. The TPA711 BTL amplifier consists of two linear amplifiers driving both ends of the load. There are several potential benefits to this differential drive configuration but initially consider power to the load. The differential drive to the speaker means that as one side is slewing up, the other side is slewing down, and vice versa. This, in effect, doubles the voltage swing on the load as compared to a ground referenced load. Plugging $2 \times V_{O(PP)}$ into the power equation, where voltage is squared, yields $4 \times$ the output power from the same supply rail and load impedance (see equation 1).

$$V_{(rms)} = \frac{V_{O(PP)}}{2\sqrt{2}} \tag{1}$$

$$\text{Power} = \frac{V_{(rms)}^2}{R_L}$$

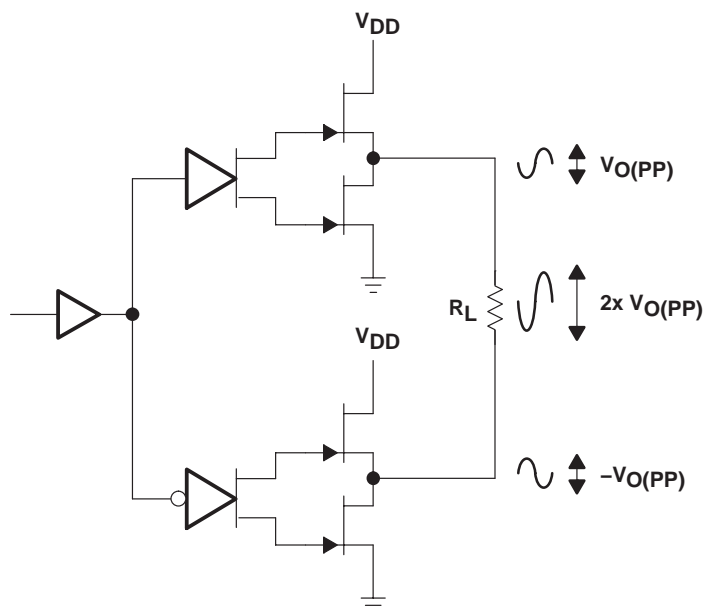


Figure 48. Bridge-Tied Load Configuration

In a typical portable handheld equipment sound channel operating at 3.3 V, bridging raises the power into an 8-Ω speaker from a singled-ended (SE, ground reference) limit of 62.5 mW to 250 mW. In sound power that is a 6-dB improvement, which is loudness that can be heard. In addition to increased power there are frequency response concerns. Consider the single-supply SE configuration shown in Figure 49. A coupling capacitor is required to block the dc offset voltage from reaching the load. These capacitors can be quite large (approximately 33 μF to 1000 μF) so they tend to be expensive, heavy, occupy valuable PCB area, and have the additional drawback of limiting low-frequency performance of the system. This frequency-limiting effect is due to the high pass filter network created with the speaker impedance and the coupling capacitance and is calculated with equation 2.

$$f_c = \frac{1}{2\pi R_L C_C} \tag{2}$$

APPLICATION INFORMATION

bridged-tied load versus single-ended mode (continued)

For example, a 68- μF capacitor with an 8- Ω speaker would attenuate low frequencies below 293 Hz. The BTL configuration cancels the dc offsets, which eliminates the need for the blocking capacitors. Low-frequency performance is then limited only by the input network and speaker response. Cost and PCB space are also minimized by eliminating the bulky coupling capacitor.

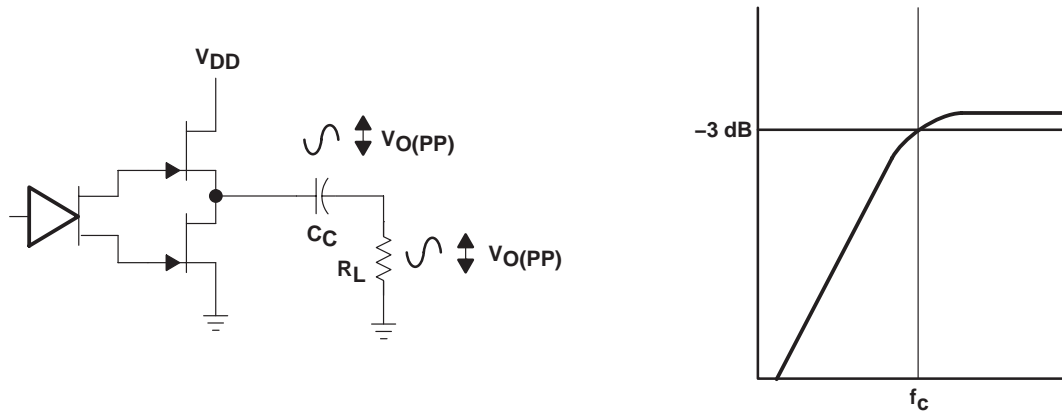


Figure 49. Single-Ended Configuration and Frequency Response

Increasing power to the load does carry a penalty of increased internal power dissipation. The increased dissipation is understandable considering that the BTL configuration produces 4 \times the output power of the SE configuration. Internal dissipation versus output power is discussed further in the *thermal considerations* section.

BTL amplifier efficiency

Linear amplifiers are notoriously inefficient. The primary cause of these inefficiencies is voltage drop across the output stage transistors. There are two components of the internal voltage drop. One is the headroom or dc voltage drop that varies inversely to output power. The second component is due to the sinewave nature of the output. The total voltage drop can be calculated by subtracting the RMS value of the output voltage from V_{DD} . The internal voltage drop multiplied by the RMS value of the supply current, $I_{DD\text{rms}}$, determines the internal power dissipation of the amplifier.

An easy-to-use equation to calculate efficiency starts out being equal to the ratio of power from the power supply to the power delivered to the load. To accurately calculate the RMS values of power in the load and in the amplifier, the current and voltage waveform shapes must first be understood (see Figure 50).

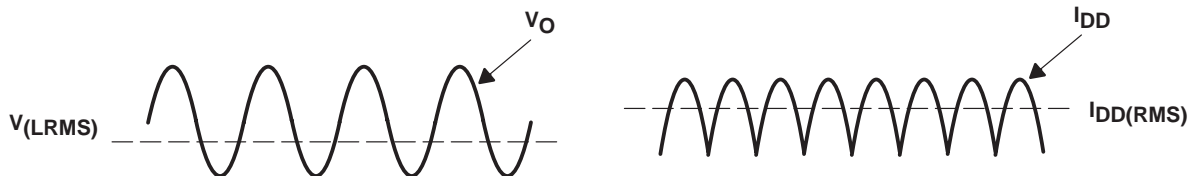


Figure 50. Voltage and Current Waveforms for BTL Amplifiers

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BTL amplifier efficiency (continued)

Although the voltages and currents for SE and BTL are sinusoidal in the load, currents from the supply are very different between SE and BTL configurations. In an SE application the current waveform is a half-wave rectified shape, whereas in BTL it is a full-wave rectified waveform. This means RMS conversion factors are different. Keep in mind that for most of the waveform, both the push and pull transistors are not on at the same time, which supports the fact that each amplifier in the BTL device only draws current from the supply for half the waveform. The following equations are the basis for calculating amplifier efficiency.

$$\text{Efficiency} = \frac{P_L}{P_{\text{SUP}}} \quad (3)$$

where

$$P_L = \frac{V_{L\text{rms}}^2}{R_L} = \frac{V_p^2}{2R_L}$$

$$V_{L\text{rms}} = \frac{V_P}{\sqrt{2}}$$

$$P_{\text{SUP}} = V_{DD} I_{DD\text{rms}} = \frac{V_{DD} 2V_P}{\pi R_L}$$

$$I_{DD\text{rms}} = \frac{2V_P}{\pi R_L}$$

$$\text{Efficiency of a BTL configuration} = \frac{\pi V_P}{4V_{DD}} = \frac{\pi (2 P_L R_L)^{1/2}}{4V_{DD}} \quad (4)$$

Table 1 employs equation 4 to calculate efficiencies for three different output power levels. The efficiency of the amplifier is quite low for lower power levels and rises sharply as power to the load is increased, resulting in a nearly flat internal power dissipation over the normal operating range. The internal dissipation at full output power is less than in the half power range. Calculating the efficiency for a specific system is the key to proper power supply design.

Table 1. Efficiency Vs Output Power in 3.3-V 8-Ω BTL Systems

OUTPUT POWER (W)	EFFICIENCY (%)	PEAK VOLTAGE (V)	INTERNAL DISSIPATION (W)
0.125	33.6	1.41	0.26
0.25	47.6	2.00	0.29
0.375	58.3	2.45†	0.28

† High-peak voltage values cause the THD to increase.

A final point to remember about linear amplifiers (either SE or BTL) is how to manipulate the terms in the efficiency equation to utmost advantage when possible. In equation 4, V_{DD} is in the denominator. This indicates that as V_{DD} goes down, efficiency goes up.

APPLICATION INFORMATION

application schematic

Figure 51 is a schematic diagram of a typical handheld audio application circuit, configured for a gain of -10 V/V .

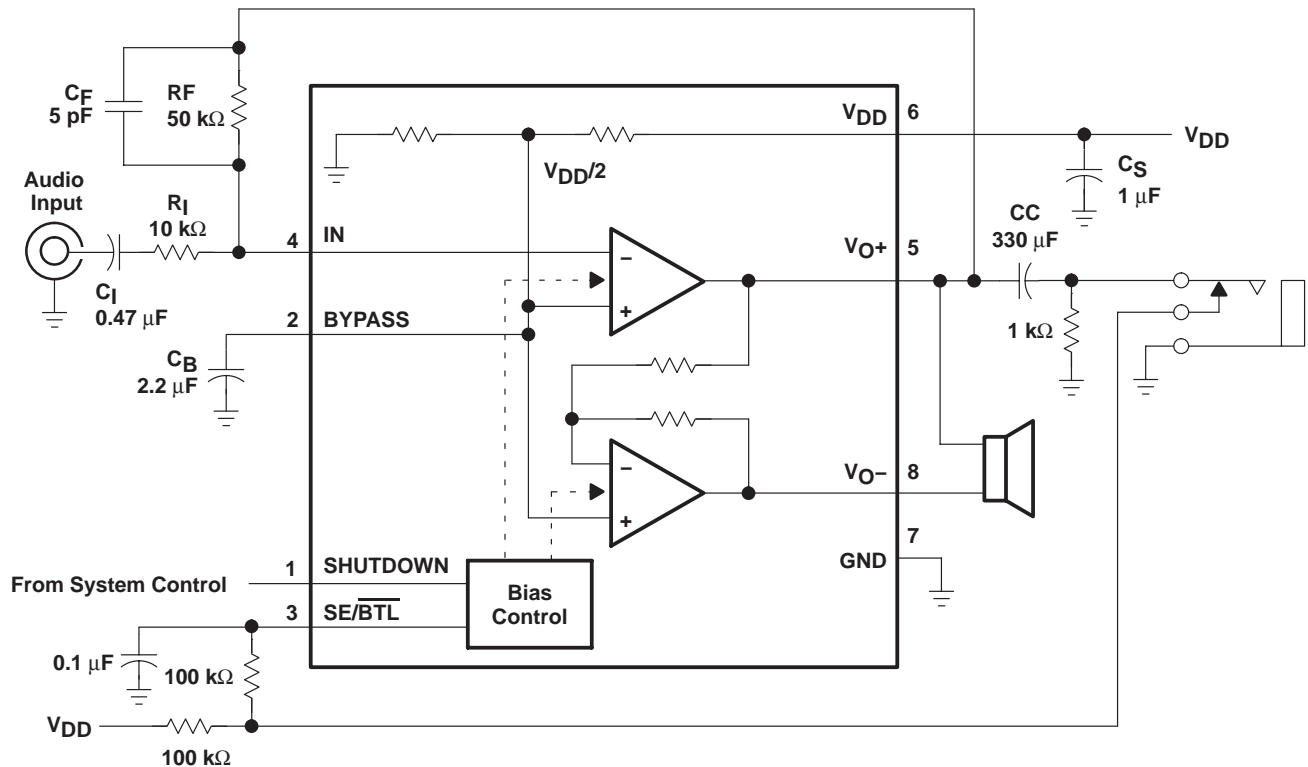


Figure 51. TPA711 Application Circuit

The following sections discuss the selection of the components used in Figure 51.

component selection

gain setting resistors, R_F and R_I

The gain for each audio input of the TPA711 is set by resistors R_F and R_I according to equation 5 for BTL mode.

$$\text{BTL gain} = -2 \left(\frac{R_F}{R_I} \right) \quad (5)$$

BTL mode operation brings about the factor 2 in the gain equation due to the inverting amplifier mirroring the voltage swing across the load. Given that the TPA711 is a MOS amplifier, the input impedance is very high; consequently input leakage currents are not generally a concern, although noise in the circuit increases as the value of R_F increases. In addition, a certain range of R_F values is required for proper start-up operation of the amplifier. Taken together it is recommended that the effective impedance seen by the inverting node of the amplifier be set between 5 kΩ and 20 kΩ. The effective impedance is calculated in equation 6.

$$\text{Effective impedance} = \frac{R_F R_I}{R_F + R_I} \quad (6)$$

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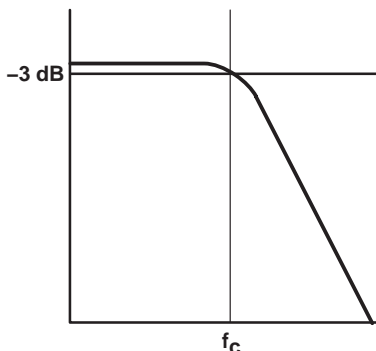
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component selection (continued)

As an example consider an input resistance of 10 kΩ and a feedback resistor of 50 kΩ. The BTL gain of the amplifier would be -10 V/V and the effective impedance at the inverting terminal would be 8.3 kΩ, which is well within the recommended range.

For high performance applications, metal film resistors are recommended because they tend to have lower noise levels than carbon resistors. For values of R_F above 50 kΩ, the amplifier tends to become unstable due to a pole formed from R_F and the inherent input capacitance of the MOS input structure. For this reason, a small compensation capacitor of approximately 5 pF should be placed in parallel with R_F when R_F is greater than 50 kΩ. This, in effect, creates a low pass filter network with the cutoff frequency defined in equation 7.

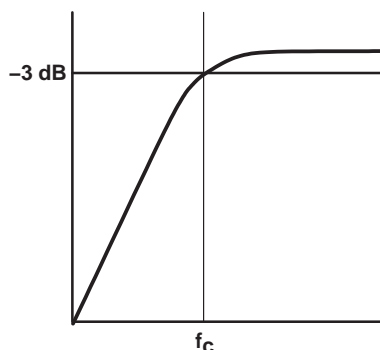


$$f_{c(\text{lowpass})} = \frac{1}{2\pi R_F C_F} \quad (7)$$

For example, if R_F is 100 kΩ and C_F is 5 pF, then f_c is 318 kHz, which is well outside of the audio range.

input capacitor, C_I

In the typical application an input capacitor, C_I , is required to allow the amplifier to bias the input signal to the proper dc level for optimum operation. In this case, C_I and R_I form a high-pass filter with the corner frequency determined in equation 8.



$$f_{c(\text{highpass})} = \frac{1}{2\pi R_I C_I} \quad (8)$$

The value of C_I is important to consider as it directly affects the bass (low frequency) performance of the circuit. Consider the example where R_I is 10 kΩ and the specification calls for a flat bass response down to 40 Hz. Equation 8 is reconfigured as equation 9.

$$C_I = \frac{1}{2\pi R_I f_c} \quad (9)$$

APPLICATION INFORMATION

component selection (continued)

In this example, C_I is $0.40 \mu\text{F}$, so one would likely choose a value in the range of $0.47 \mu\text{F}$ to $1 \mu\text{F}$. A further consideration for this capacitor is the leakage path from the input source through the input network (R_I , C_I) and the feedback resistor (R_F) to the load. This leakage current creates a dc offset voltage at the input to the amplifier that reduces useful headroom, especially in high gain applications. For this reason a low-leakage tantalum or ceramic capacitor is the best choice. When polarized capacitors are used, the positive side of the capacitor should face the amplifier input in most applications, as the dc level there is held at $V_{DD}/2$, which is likely higher than the source dc level. It is important to confirm the capacitor polarity in the application.

power supply decoupling, C_S

The TPA711 is a high-performance CMOS audio amplifier that requires adequate power supply decoupling to ensure the output total harmonic distortion (THD) is as low as possible. Power supply decoupling also prevents oscillations for long lead lengths between the amplifier and the speaker. The optimum decoupling is achieved by using two capacitors of different types that target different types of noise on the power supply leads. For higher frequency transients, spikes, or digital hash on the line, a good low equivalent-series-resistance (ESR) ceramic capacitor, typically $0.1 \mu\text{F}$ placed as close as possible to the device V_{DD} lead, works best. For filtering lower-frequency noise signals, a larger aluminum electrolytic capacitor of $10 \mu\text{F}$ or greater placed near the audio power amplifier is recommended.

midrail bypass capacitor, C_B

The midrail bypass capacitor, C_B , is the most critical capacitor and serves several important functions. During start-up or recovery from shutdown mode, C_B determines the rate at which the amplifier starts up. The second function is to reduce noise produced by the power supply caused by coupling into the output drive signal. This noise is from the midrail generation circuit internal to the amplifier, which appears as degraded PSRR THD + N. The capacitor is fed from a $250\text{-k}\Omega$ source inside the amplifier. To keep the start-up pop as low as possible, the relationship shown in equation 10 should be maintained. This insures the input capacitor is fully charged before the bypass capacitor is fully charged and the amplifier starts up.

$$\frac{10}{(C_B \times 250 \text{ k}\Omega)} \leq \frac{1}{(R_F + R_I) C_I} \quad (10)$$

As an example, consider a circuit where C_B is $2.2 \mu\text{F}$, C_I is $0.47 \mu\text{F}$, R_F is $50 \text{ k}\Omega$, and R_I is $10 \text{ k}\Omega$. Inserting these values into the equation 10 we get:

$$18.2 \leq 35.5$$

which satisfies the rule. Bypass capacitor, C_B , values of $0.1 \mu\text{F}$ to $2.2 \mu\text{F}$ ceramic or tantalum low-ESR capacitors are recommended for the best THD and noise performance.

single-ended operation

In SE mode (see Figure 51), the load is driven from the primary amplifier output (V_{O+} , terminal 5).

In SE mode the gain is set by the R_F and R_I resistors and is shown in equation 11. Since the inverting amplifier is not used to mirror the voltage swing on the load, the factor of 2, from equation 5, is not included.

$$\text{SE Gain} = - \left(\frac{R_F}{R_I} \right) \quad (11)$$

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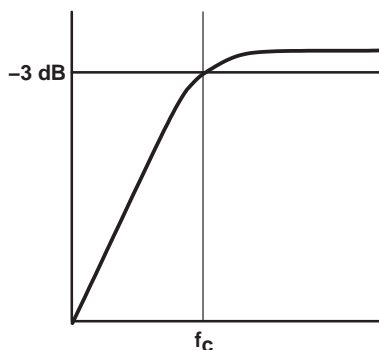
component selection (continued)

The output coupling capacitor required in single-supply SE mode also places additional constraints on the selection of other components in the amplifier circuit. The rules described earlier still hold with the addition of the following relationship:

$$\frac{10}{(C_B \times 250 \text{ k}\Omega)} \leq \frac{1}{(R_F + R_I) C_I} \ll \frac{1}{R_L C_C} \quad (12)$$

output coupling capacitor, C_C

In the typical single-supply SE configuration, an output coupling capacitor (C_C) is required to block the dc bias at the output of the amplifier, thus preventing dc currents in the load. As with the input coupling capacitor, the output coupling capacitor and impedance of the load form a high-pass filter governed by equation 13.



$$f_{c(\text{high})} = \frac{1}{2\pi R_L C_C} \quad (13)$$

The main disadvantage, from a performance standpoint, is the load impedances are typically small, which drives the low-frequency corner higher, degrading the bass response. Large values of C_C are required to pass low frequencies into the load. Consider the example where a C_C of 330 μF is chosen and loads vary from 4 Ω , 8 Ω , 32 Ω , and 47 k Ω . Table 2 summarizes the frequency response characteristics of each configuration.

Table 2. Common Load Impedances Vs Low Frequency Output Characteristics in SE Mode

R_L	C_C	LOWEST FREQUENCY
8 Ω	330 μF	60 Hz
32 Ω	330 μF	15 Hz
47,000 Ω	330 μF	0.01 Hz

As Table 2 indicates, an 8- Ω load is adequate, earphone response is good, and drive into line level inputs (a home stereo for example) is exceptional.

APPLICATION INFORMATION

SE/BTL operation

The ability of the TPA711 to easily switch between BTL and SE modes is one of its most important cost-saving features. This feature eliminates the requirement for an additional earphone amplifier in applications where internal speakers are driven in BTL mode but external earphone or speaker must be accommodated. Internal to the TPA711, two separate amplifiers drive V_{O+} and V_{O-} . The SE/BTL input (terminal 3) controls the operation of the follower amplifier that drives V_{O-} (terminal 8). When SE/BTL is held low, the amplifier is on and the TPA711 is in the BTL mode. When SE/BTL is held high, the V_{O-} amplifier is in a high output impedance state, which configures the TPA711 as an SE driver from V_{O+} (terminal 5). I_{DD} is reduced by approximately one-half in SE mode. Control of the SE/BTL input can be from a logic-level TTL source or, more typically, from a resistor divider network as shown in Figure 52.

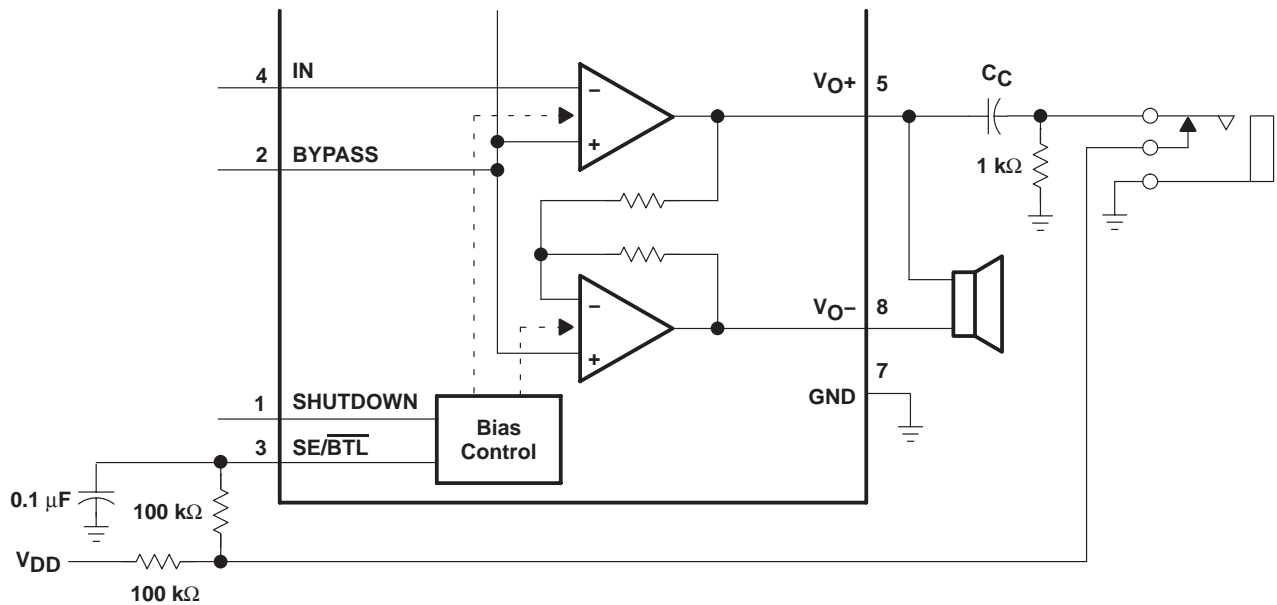


Figure 52. TPA711 Resistor Divider Network Circuit

Using a readily available 1/8-in. (3.5 mm) mono earphone jack, the control switch is closed when no plug is inserted. When closed, the 100-kΩ/1-kΩ divider pulls the SE/BTL input low. When a plug is inserted, the 1-kΩ resistor is disconnected and the SE/BTL input is pulled high. When the input goes high, the V_{O-} amplifier is shut down causing the BTL speaker to mute (virtually open-circuits the speaker). The V_{O+} amplifier then drives through the output capacitor (C_C) into the earphone jack.

using low-ESR capacitors

Low-ESR capacitors are recommended throughout this applications section. A real (as opposed to ideal) capacitor can be modeled simply as a resistor in series with an ideal capacitor. The voltage drop across this resistor minimizes the beneficial effects of the capacitor in the circuit. The lower the equivalent value of this resistance the more the real capacitor behaves like an ideal capacitor.

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APPLICATION INFORMATION

5-V versus 3.3-V operation

The TPA711 operates over a supply range of 2.5 V to 5.5 V. This data sheet provides full specifications for 5-V and 3.3-V operation, as these are considered to be the two most common standard voltages. There are no special considerations for 3.3-V versus 5-V operation with respect to supply bypassing, gain setting, or stability. The most important consideration is that of output power. Each amplifier in TPA711 can produce a maximum voltage swing of $V_{DD} - 1$ V. This means, for 3.3-V operation, clipping starts to occur when $V_{O(PP)} = 2.3$ V as opposed to $V_{O(PP)} = 4$ V at 5 V. The reduced voltage swing subsequently reduces maximum output power into an 8- Ω load before distortion becomes significant.

Operation from 3.3-V supplies, as can be shown from the efficiency formula in equation 4, consumes approximately two-thirds the supply power of operation from 5-V supplies for a given output-power level.

headroom and thermal considerations

Linear power amplifiers dissipate a significant amount of heat in the package under normal operating conditions. A typical music CD requires 12 dB to 15 dB of dynamic headroom to pass the loudest portions without distortion as compared with the average power output. From the TPA711 data sheet, one can see that when the TPA711 is operating from a 5-V supply into a 8- Ω speaker that 700 mW peaks are available. Converting watts to dB:

$$P_{dB} = 10\text{Log}\left(\frac{P_W}{P_{ref}}\right) = 10\text{Log}\left(\frac{700\text{ mW}}{1\text{W}}\right) = -1.5\text{ dB}$$

Subtracting the headroom restriction to obtain the average listening level without distortion yields:

- 1.5 dB – 15 dB = -16.5 (15 dB headroom)
- 1.5 dB – 12 dB = -13.5 (12 dB headroom)
- 1.5 dB – 9 dB = -10.5 (9 dB headroom)
- 1.5 dB – 6 dB = -7.5 (6 dB headroom)
- 1.5 dB – 3 dB = -4.5 (3 dB headroom)

Converting dB back into watts:

$$\begin{aligned} P_W &= 10^{P_{dB}/10} \times P_{ref} \\ &= 22\text{ mW (15 dB headroom)} \\ &= 44\text{ mW (12 dB headroom)} \\ &= 88\text{ mW (9 dB headroom)} \\ &= 175\text{ mW (6 dB headroom)} \\ &= 350\text{ mW (3 dB headroom)} \end{aligned}$$

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headroom and thermal considerations (continued)

This is valuable information to consider when attempting to estimate the heat dissipation requirements for the amplifier system. Comparing the absolute worst case, which is 700 mW of continuous power output with 0 dB of headroom, against 12 dB and 15 dB applications drastically affects maximum ambient temperature ratings for the system. Using the power dissipation curves for a 5-V, 8- Ω system, the internal dissipation in the TPA711 and maximum ambient temperatures is shown in Table 3.

Table 3. TPA711 Power Rating, 5-V, 8- Ω , BTL

PEAK OUTPUT POWER (mW)	AVERAGE OUTPUT POWER	POWER DISSIPATION (mW)	D PACKAGE (SOIC)	DGN PACKAGE (MSOP)
			MAXIMUM AMBIENT TEMPERATURE	MAXIMUM AMBIENT TEMPERATURE
700	700 mW	675	34°C	110°C
700	350 mW (3 dB)	595	47°C	115°C
700	176 mW (6 dB)	475	68°C	122°C
700	88 mW (9 dB)	350	89°C	125°C
700	44 mW (12 dB)	225	111°C	125°C

Table 3 shows that the TPA711 can be used to its full 700-mW rating without any heat sinking in still air up to 110°C and 34°C for the DGN package (MSOP) and D package (SOIC) respectively.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TPA711D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	711	Samples
TPA711DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	711	Samples
TPA711DGN	ACTIVE	MSOP-PowerPAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABB	Samples
TPA711DGNG4	ACTIVE	MSOP-PowerPAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABB	Samples
TPA711DGNR	ACTIVE	MSOP-PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABB	Samples
TPA711DGNRG4	ACTIVE	MSOP-PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABB	Samples
TPA711DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	711	Samples
TPA711DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	711	Samples
TPA711EVM	OBSOLETE					TBD	Call TI	Call TI	-40 to 85		

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Only one of markings shown within the brackets will appear on the physical device.

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TAPE AND REEL INFORMATION
REEL DIMENSIONS

TAPE DIMENSIONS


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPA711DGNR	MSOP-Power PAD	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPA711DGNR	MSOP-Power PAD	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPA711DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPA711DGNR	MSOP-PowerPAD	DGN	8	2500	364.0	364.0	27.0
TPA711DGNR	MSOP-PowerPAD	DGN	8	2500	358.0	335.0	35.0
TPA711DR	SOIC	D	8	2500	367.0	367.0	35.0

DGN (S-PDSO-G8)

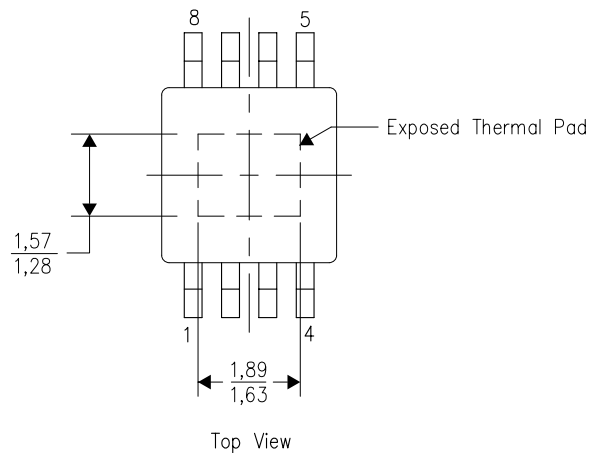
PowerPAD™ PLASTIC SMALL OUTLINE

THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Exposed Thermal Pad Dimensions

4206323-2/1 12/11

NOTE: All linear dimensions are in millimeters

PowerPAD is a trademark of Texas Instruments



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
 - D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <<http://www.ti.com>>.
 - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
 - F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - $\triangle C$ Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 - $\triangle D$ Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AA.

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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